



3rd ILSF Advanced School on Synchrotron Radiation and Its Applications

September 14-16, 2013



Study of High T_c Superconducting Properties by Using Synchrotron Radiation

Hossein Khosroabadi

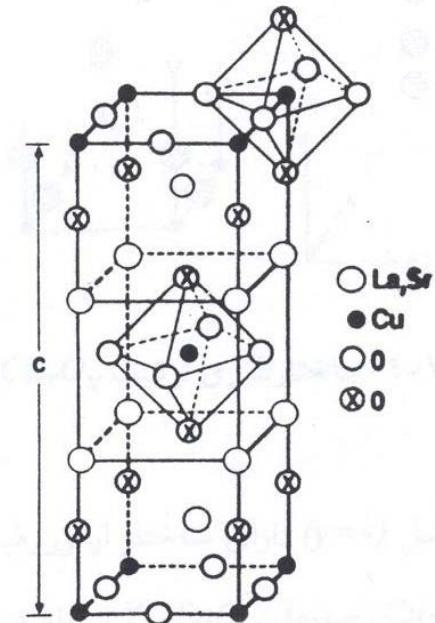
Dep of Physics, Sharif Univ. of Technology

Sep 16, 2013

High T_c Copper-Oxide Superconductors

Bednorz-Muller (Noble prize 1987)

T_c=35-135 K

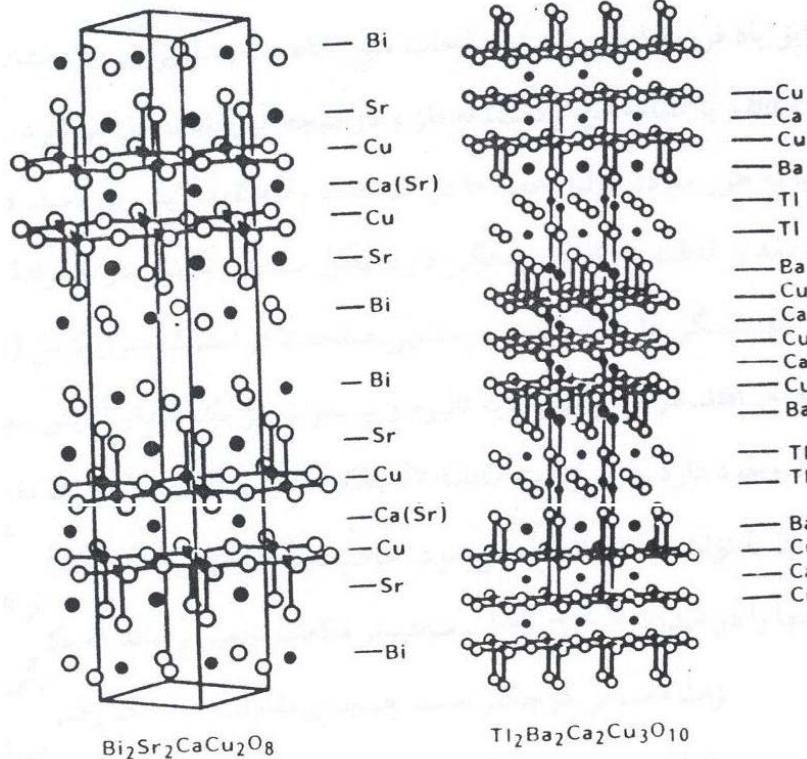
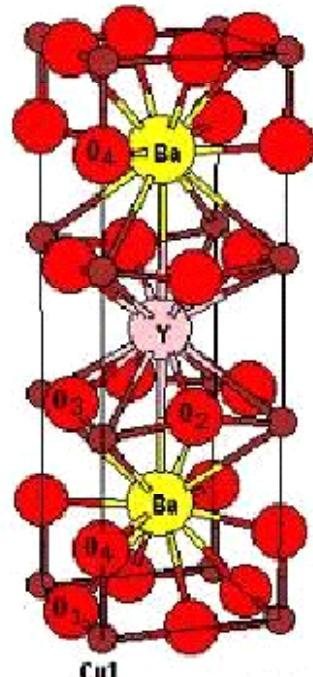


RBCO

T_c=90 K

MRL

Pr, O SIT problems



BSCCO

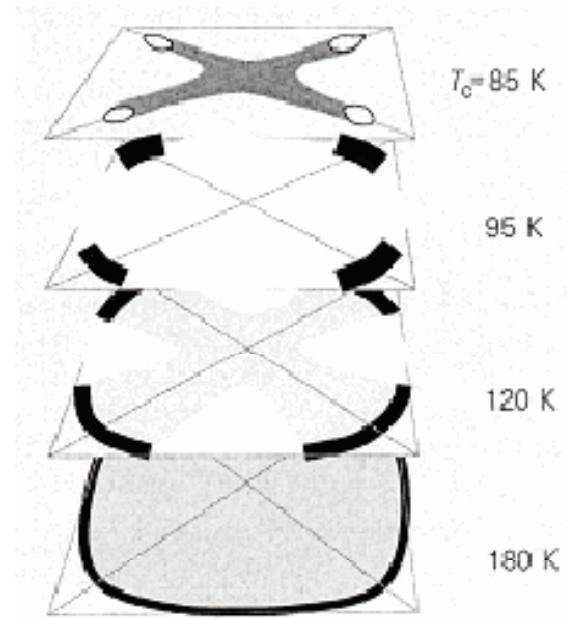
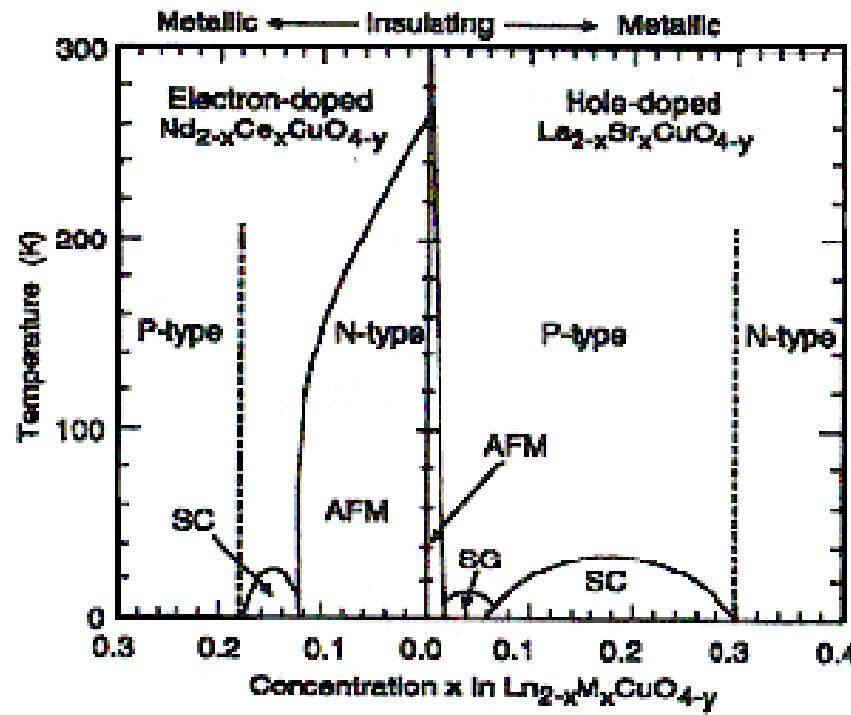
T_c=110 K

TIBCCO

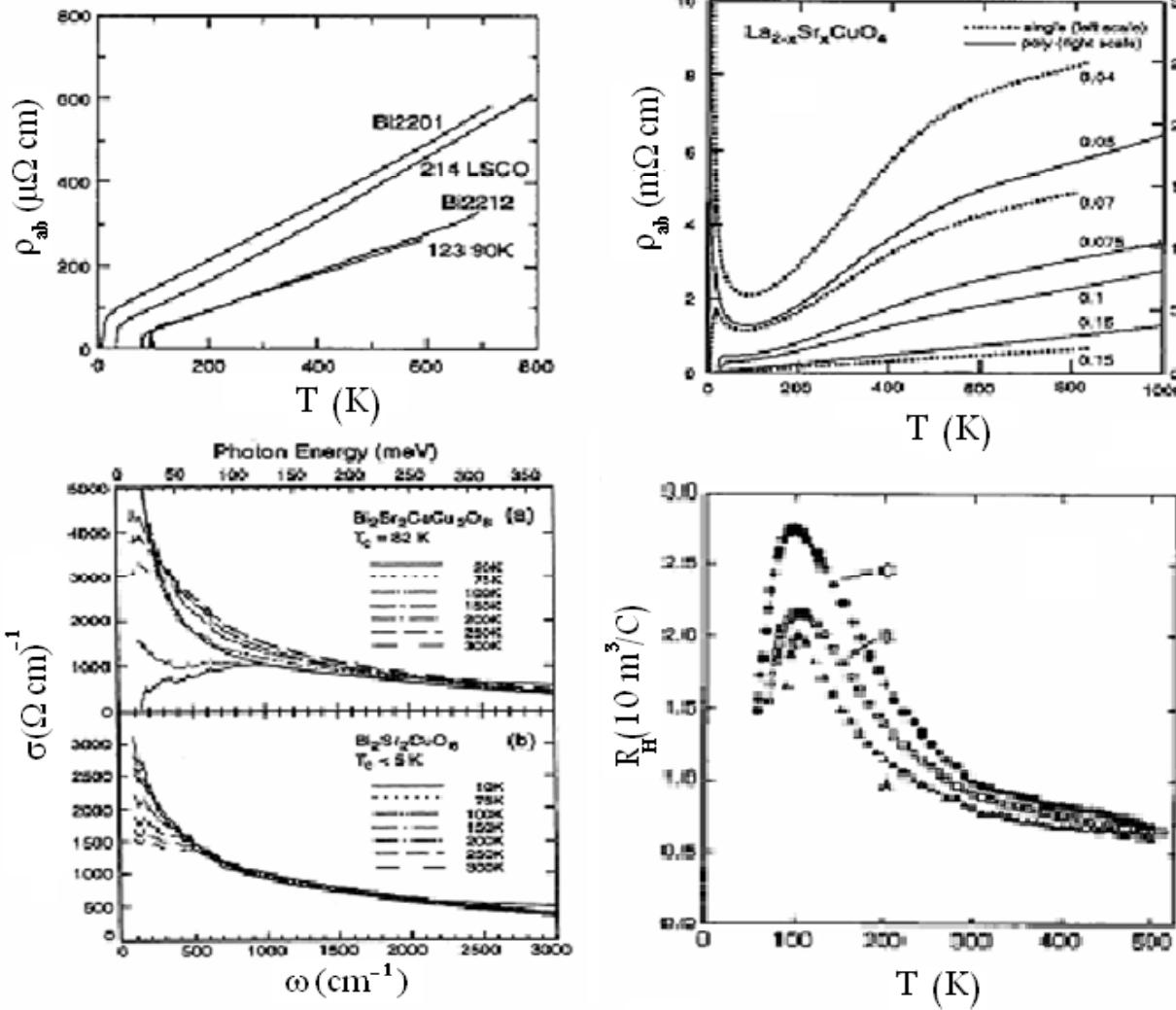
T_c=125 K

LSCO
T_c=38 K

HTSC Phase Diagram

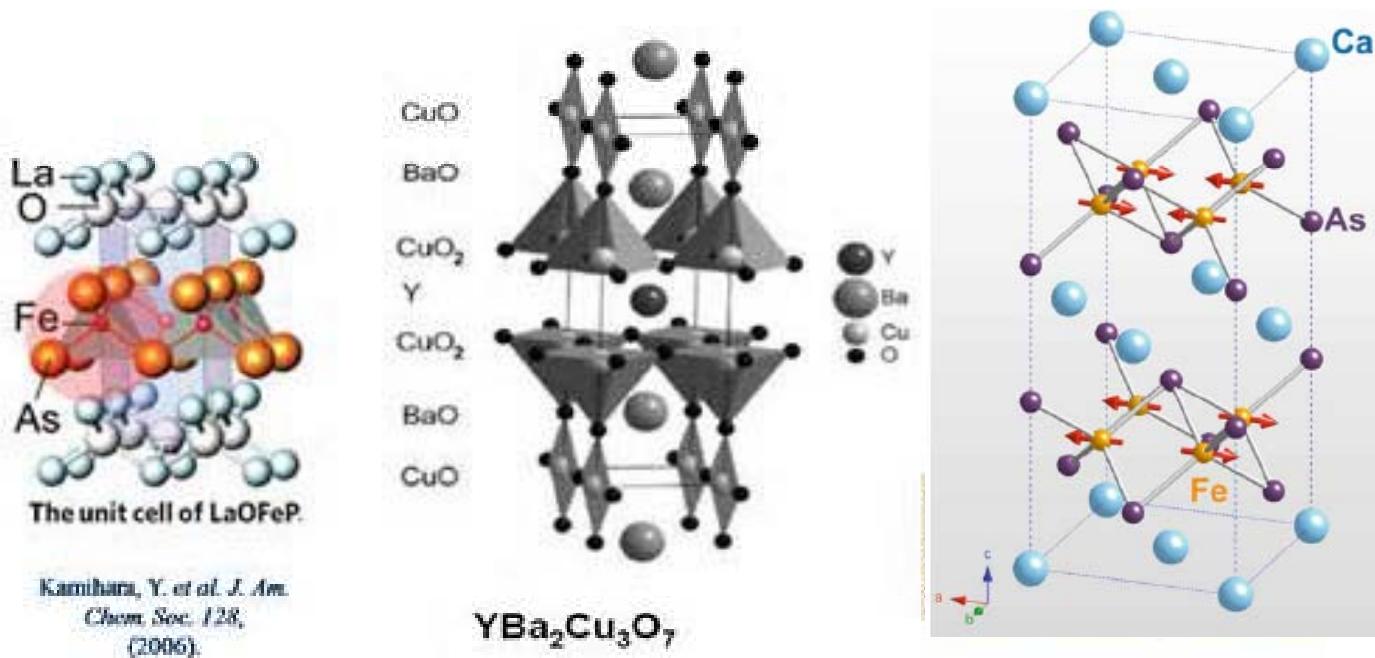


Unusual Electronic Properties of HTSCs in Normal Phase



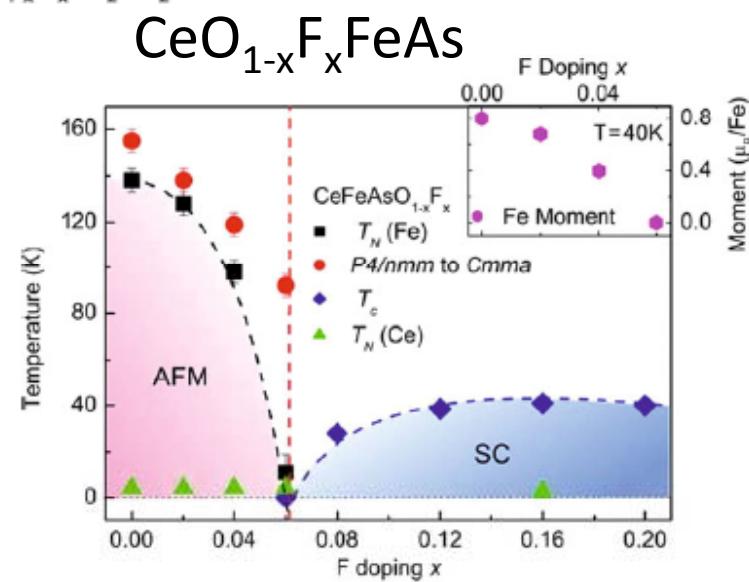
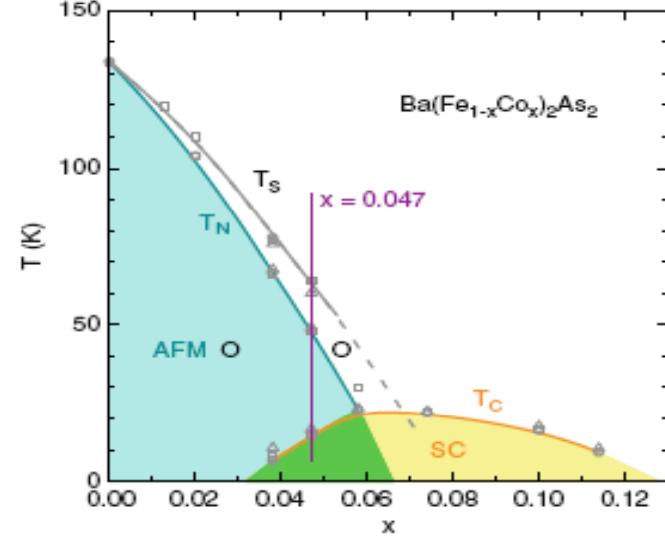
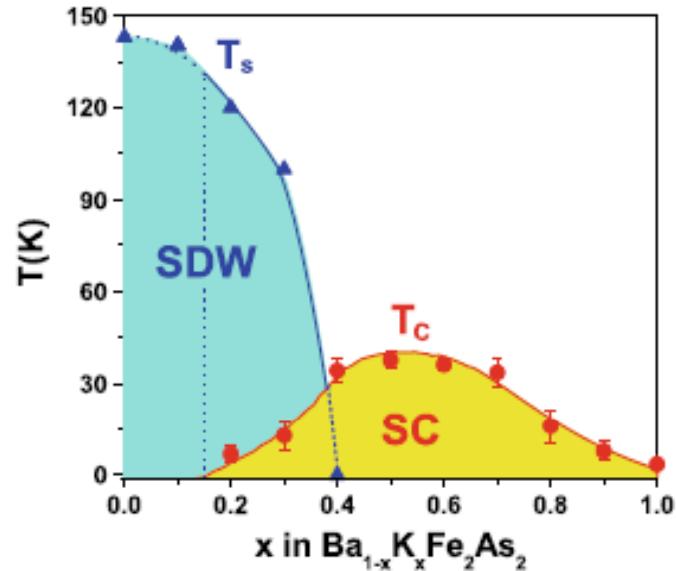
E. Dagotto, Rev. Mod. Phys. **66** (1994)763; D.N. Basov et al., Rev. Mod. Phys. **77** (2005)721.

New Superconductors



$ReOFeAs$	La	Ce	Pr	Nd	Sm	Gd
T_c , K	41	41	52	51.9	55	53.5
Reference	[27]	[9]	[10]	[28]	[11]	[29]
a , Å	4.035	3.996	3.925	3.940	3.940	
c , Å	8.740	8.648	8.595	8.496	8.496	

Phase Diagram



FeAs Research Group



J Supercond Nov Magn
DOI 10.1007/s10948-012-1717-8

ORIGINAL PAPER

Electronic and Phonon Structures of BaFe₂As₂ Superconductor by *Ab-initio* Density Functional Theory

M. Sandeghchi · H. Khosroabadi · H. Almasi ·
M. Akhavan

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Abstract Electronic and phonon structures of the BaFe₂As₂ superconductor in the magnetic-orthorhombic phase have been investigated by the ab-initio density functional theory using the pseudopotential Quantum Espresso code. Density of state and electronic band structure for this phase

potassium doping at the Ba site changes the system from the spin-density wave (SDW) metal to the superconductor having T_c as much as 38 K at $x = 0.4$ [5]. The Hall effect measurement indicates that charge carriers are hole-like. The crystal structure of BaFe₂As₂ is tetragonal with the I4/mmm

Research Challenges

Problems of theory

- Strongly Correlated: LDA-DFT does not give reasonable results
- Many Body Hamiltonian is diagonalized only for small lattice
- Complete Hamiltonian?
- doping, temperature, interactions, etc?

How Experiments can help?

Determination of crystal structure

.... Superconducting properties

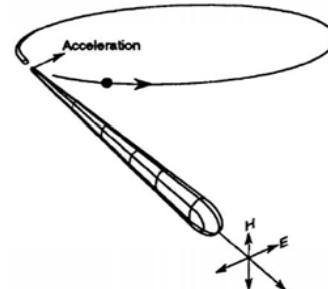
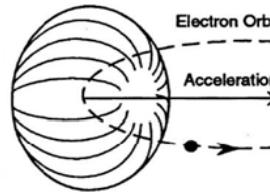
.... Phase diagram

.... Electronic structure

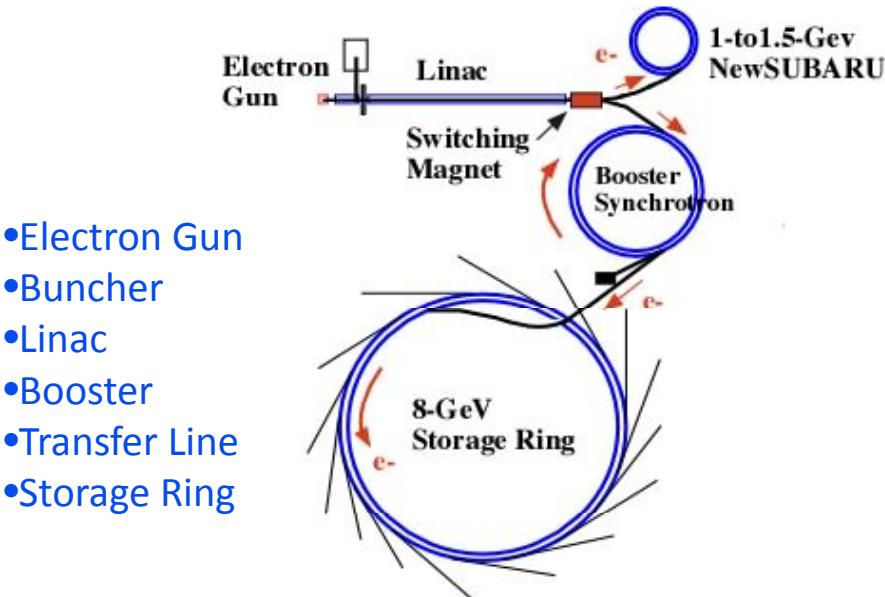
.... Phonons, magnetic excitations, etc

Light Source Accelerator

Relativistic forward focusing of Synchrotron Radiation

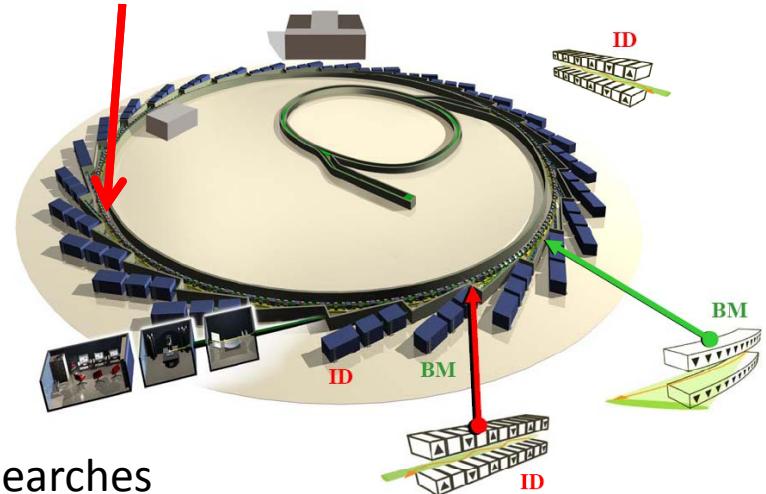


Non relativistic
Isotropic Radiation



Relativistic ($v > 99.999999 c$)
Forward Cone Radiation (mrad)

Accelerated electrons



Light Source Examples



ALBA Spain 2011
3 Gev, 268.8 m



SPring-8 Japan 1997
8 Gev, 1436 m

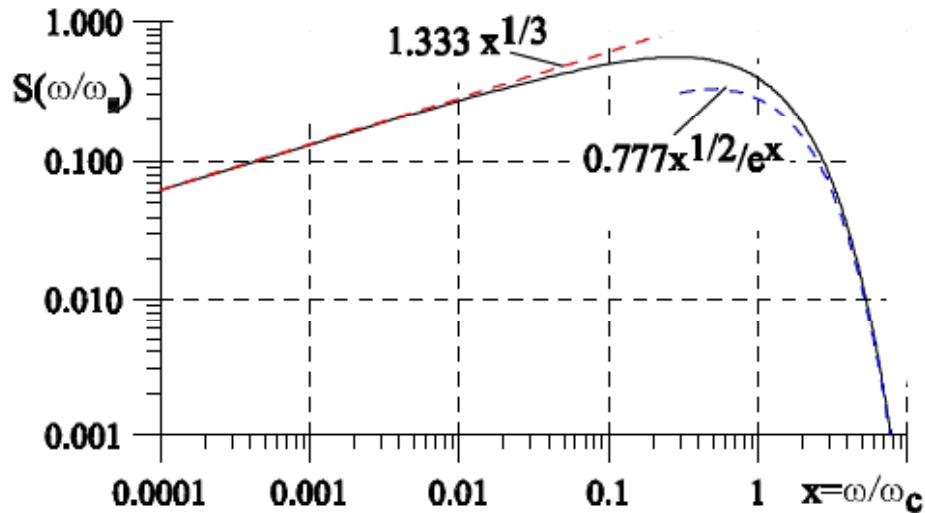


APS, USA 1996
7 Gev, 1104 m



ESRF France, 1994
6 Gev, 844 m

Radiation Properties

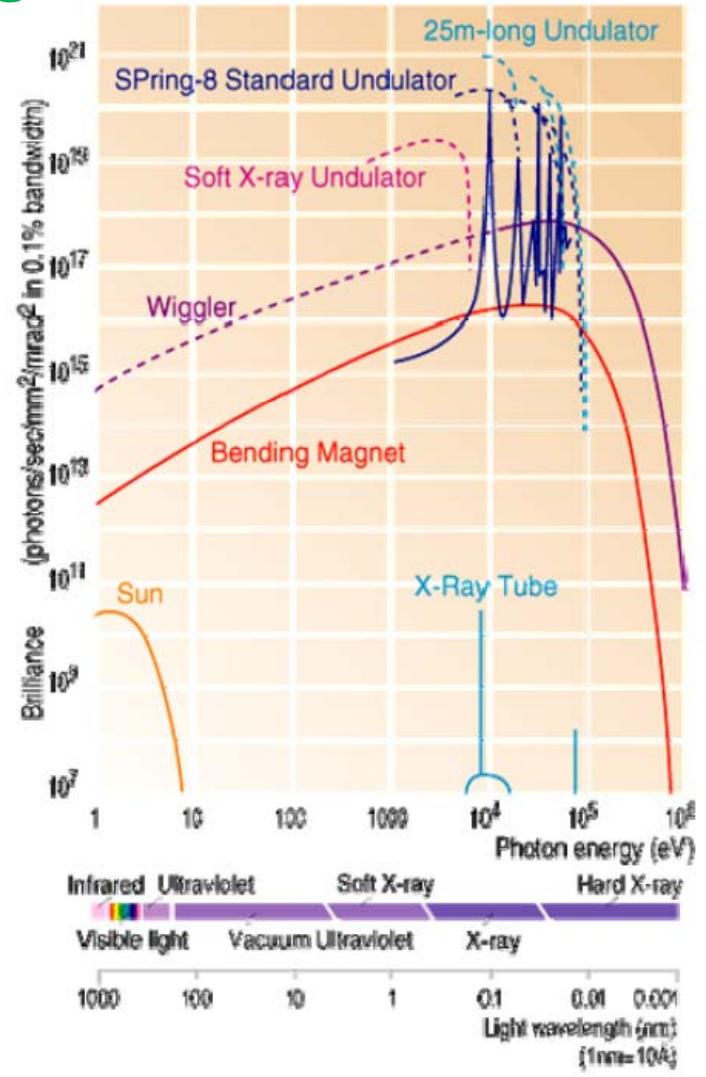


$$\frac{dN_{ph}}{d\psi} = C_\psi E I \frac{\Delta\omega}{\omega} S\left(\frac{\omega}{\omega_c}\right)$$

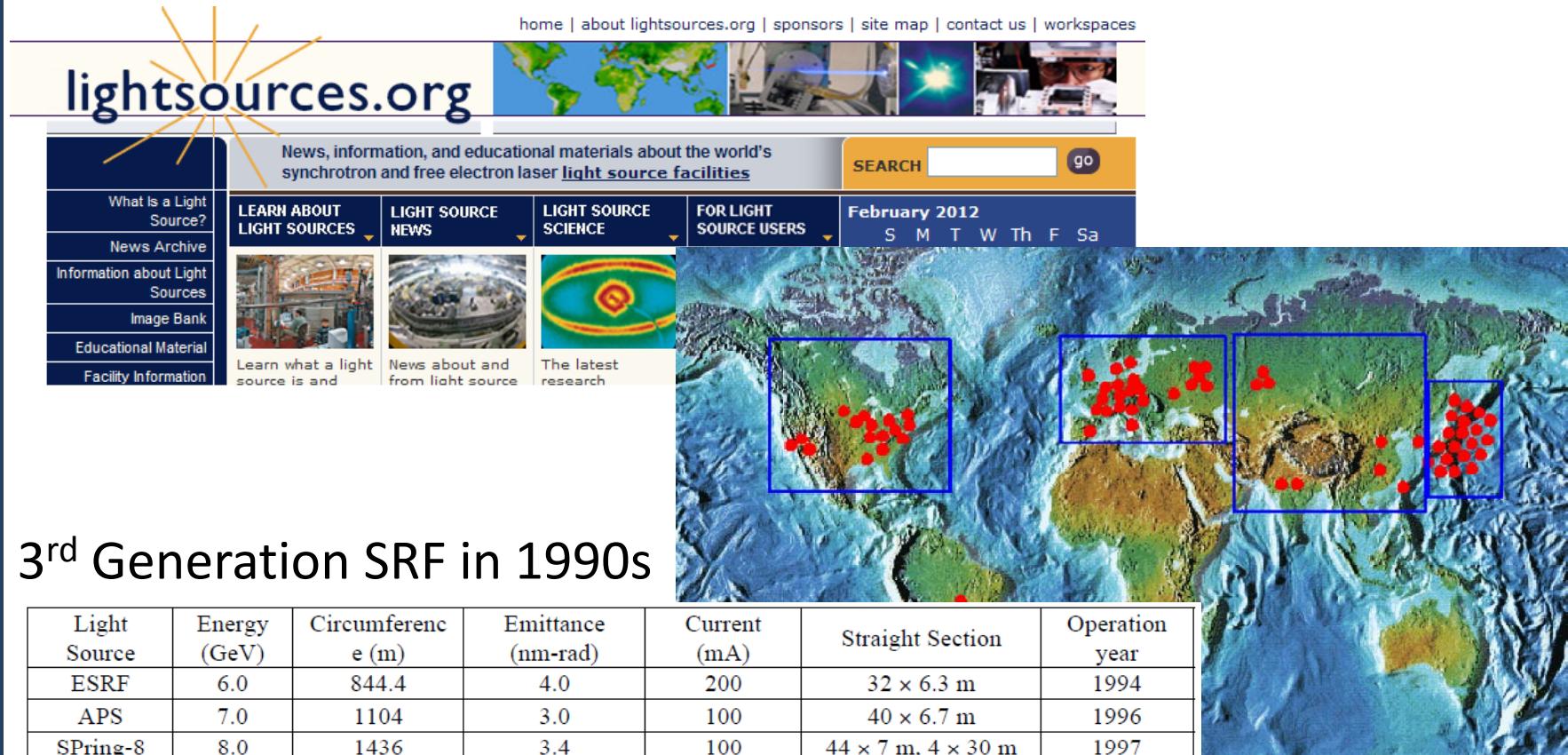
$$C_\psi = \frac{4\alpha}{9e mc^2} = 3.9614 \times 10^{19} \frac{\text{photons}}{\text{s rad A GeV}}$$

$$\varepsilon_c (\text{keV}) = 2.2183 \frac{E^3 (\text{GeV}^3)}{\rho (\text{m})} = 0.66503 E^2 (\text{GeV}^2) B (\text{T})$$

$$\mathcal{B} = \frac{N_{ph}}{4\pi^2 \sigma_x \sigma_{x'} \sigma_y \sigma_{y'} \frac{d\omega}{\omega}}$$



Statistics



3rd Generation SRF in 1990s

Light Source	Energy (GeV)	Circumference (m)	Emissance (nm·rad)	Current (mA)	Straight Section	Operation year
ESRF	6.0	844.4	4.0	200	32 × 6.3 m	1994
APS	7.0	1104	3.0	100	40 × 6.7 m	1996
SPring-8	8.0	1436	3.4	100	44 × 7 m, 4 × 30 m	1997
ALS	1.9	196.8	6.3	400	12 × 6.7 m	1993
TLS	1.5	120	25	240	6 × 6 m	1994
ELETTRA	2.4	259	7.0	300	12 × 6.1 m	1994
PLS	2.5	280.6	12.0	200	12 × 6.8 m	1995
LNLS	1.37	93.2	100	250	6 × 3 m	1997
MAX-II	1.5	90	9.0	280	10 × 3.2 m	1997
BESSY-II	1.7	240	6.1	200	8 × 4.9 m, 8 × 5.7 m	1999
Siberia-II	2.5	124	98	200	12 × 3 m	1999

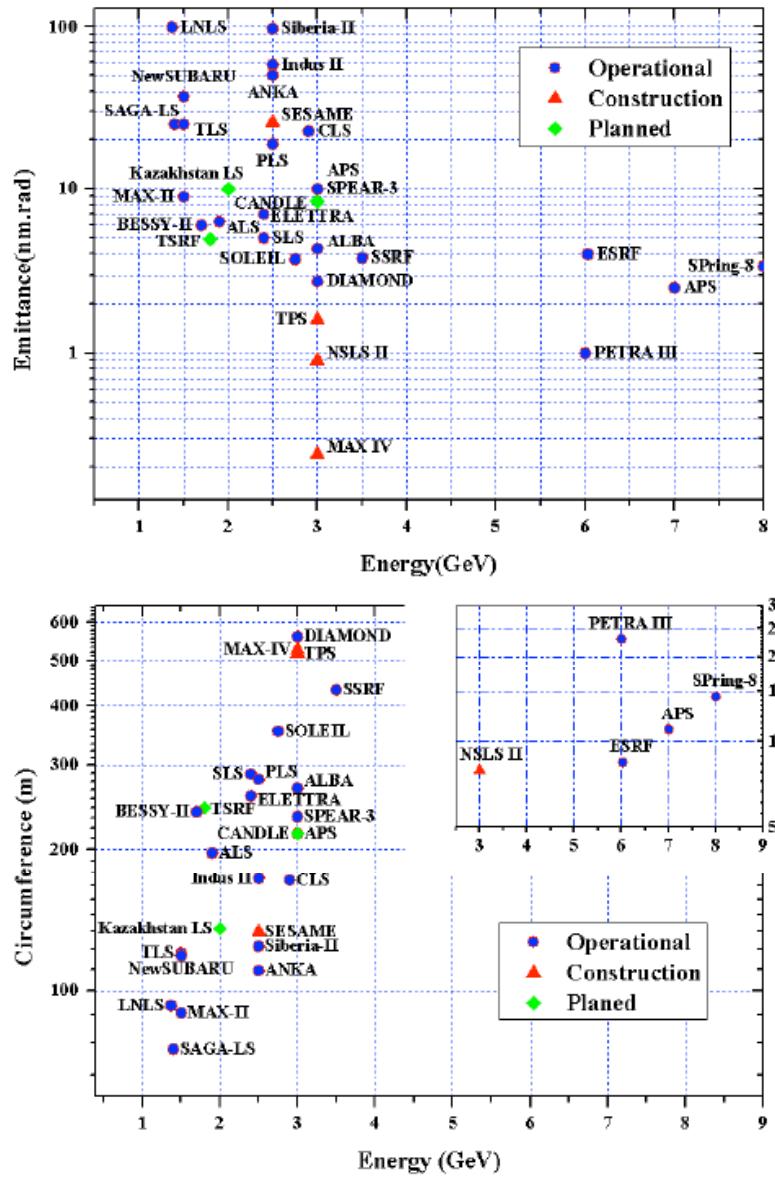
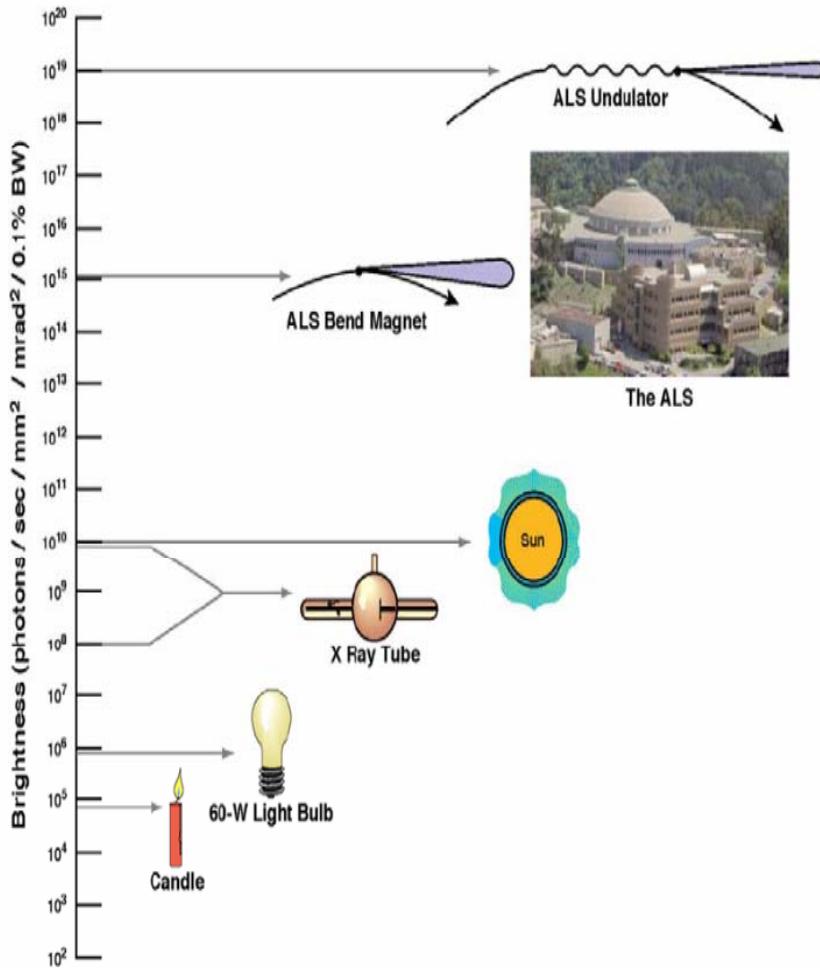
3rd Generation SRF in 2000s

Light Source	Energy (GeV)	Circumference (m)	Emittance (nm-rad)	Current (mA)	Straight Section	Operation Year
New SUBARU	1.5	118.7	38	500	4 x 2.6 m, 2 x 14 m	2000
SLS	2.4-2.7	288	5.0	400	3 x 11.7 m, 3 x 7 m, 6 x 4 m	2001
ANKA	2.5	110.4	50	200	4 x 5.6 m, 4 x 2.2 m	2002
CLS	2.9	170.88	22.7	300	12 x 5.2 m	2003
SPEAR-3	3.0	234	18	500	12 x 3 m, 4 x 4.5 m, 2 x 7.5 m	2004
SAGA-LS	1.4	75.6	7.5	300	8 x 2.5 m	2006
SOLEIL	2.75	354.1	3.74	500	4 x 12 m, 12 x 7 m, 8 x 3.8 m	2007
DIAMOND	3.0	561.6	2.7	300	6 x 11.3 m, 18 x 8.3 m	2007
ASP	3.0	216	10	200	14 x 5.4 m	2008
INDUS II	2.5	172.5	58.1	300	8 x 4.5 m	2008
SSRF	3.5	432	3.9	300	4 x 12 m, 16 x 6.5 m	2009
ALBA	3.0	268.8	4.3	400	4 x 8 m, 12 x 4.2 m, 8 x 2.6 m	2010
PETRA III	6.0	2304	1.0	100	20 x 4 m	2010

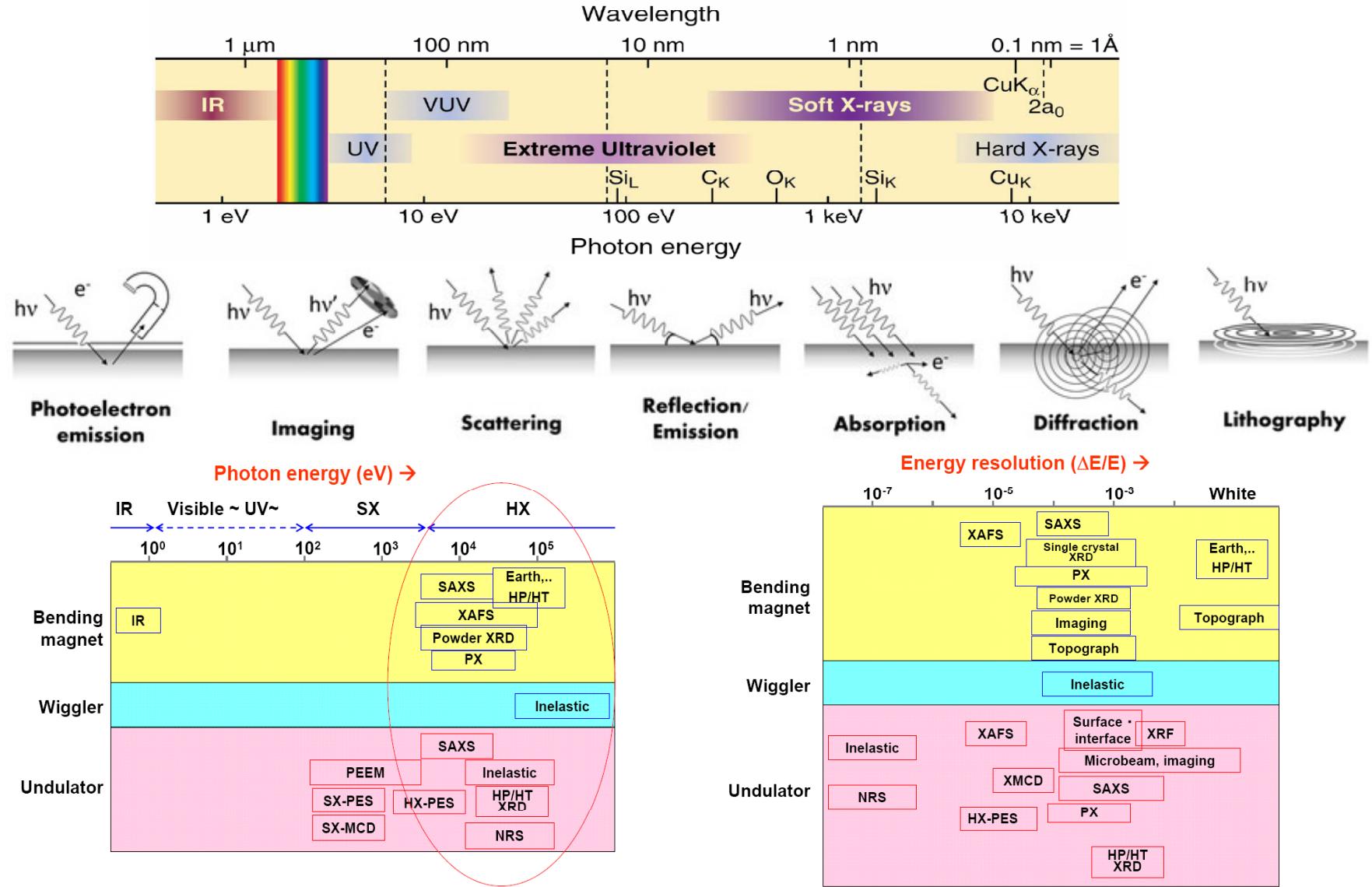
3 Generation Synchrotron Under construction

Light Source	Energy (GeV)	Circumference (m)	Emittance (nm-rad)	Current (mA)	Straight Section	Status
CANDLE	3.0	216	8.4	350	16 x 4.8 m	Planned
MAX IV	1.5/3.0	96 / 528	5.6 / 0.24	500	12 / 20 - straight sections	(2010)
PLS-II	3.0	281	5.8	400	12 X 6.8 m, 12 x 3.1 m	(2011)
TPS	3.0	518	1.7	400	18 x 7 m, 6 x 12 m	(2013)
NSLS-II	3.0	792	0.9	500	15 x 6 m, 15 x 9.3 m	(2014)
SESAME	2.5	133	26	400	4 x 5 m, 8 x 3.5 m, 4 x 1.9 m	(2014)

Characteristics

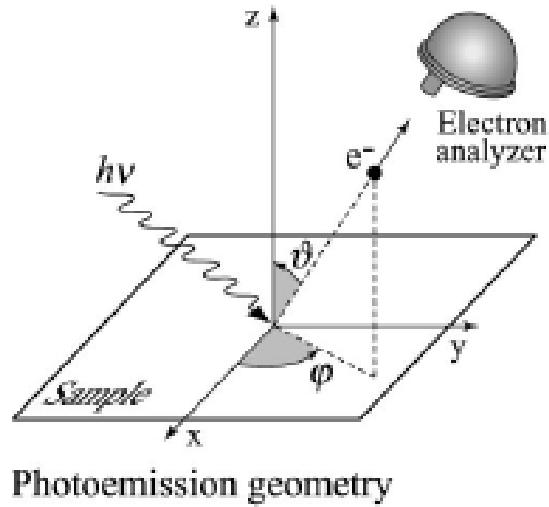


Experimental Techniques



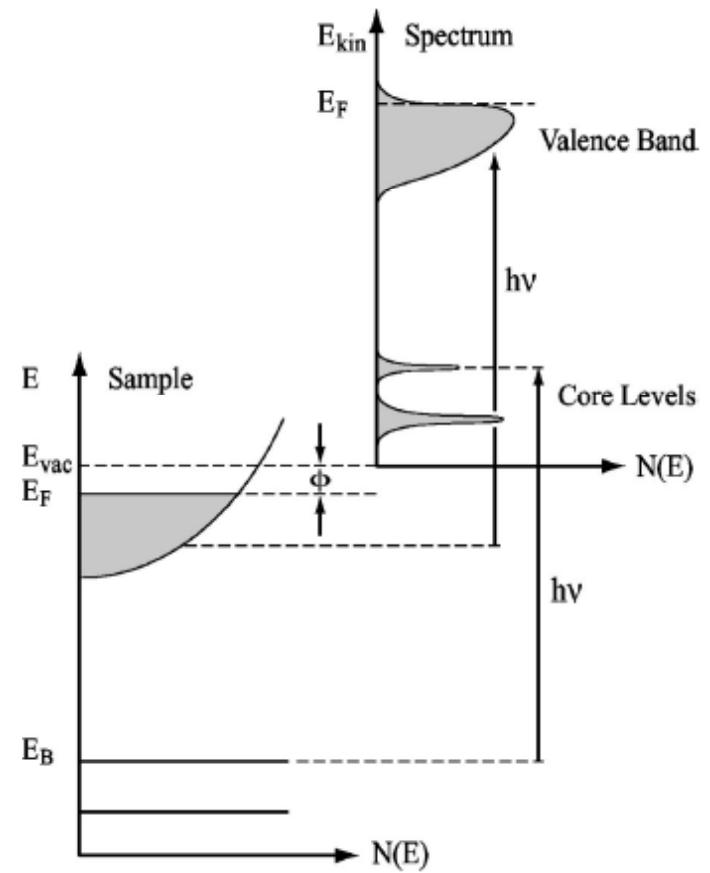
ARPES

- Angular Resolved PhotoEmission Spectroscopy
- Electronic structure (bands, Fermi surface, ...)
- Electron-phonon interaction
- Superconducting Gap structure



$$E_{kin} = h\nu - \phi - |E_B|,$$

$$p_l = \hbar k_{\parallel} = \sqrt{2mE_{kin}} \cdot \sin \theta$$



REVIEWS OF MODERN PHYSICS, VOLUME 75, APRIL 2003

Angle-resolved photoemission studies of the cuprate superconductors

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Advanced Light Source, Lawrence Berkeley National Laboratory, Berkeley, California 94720

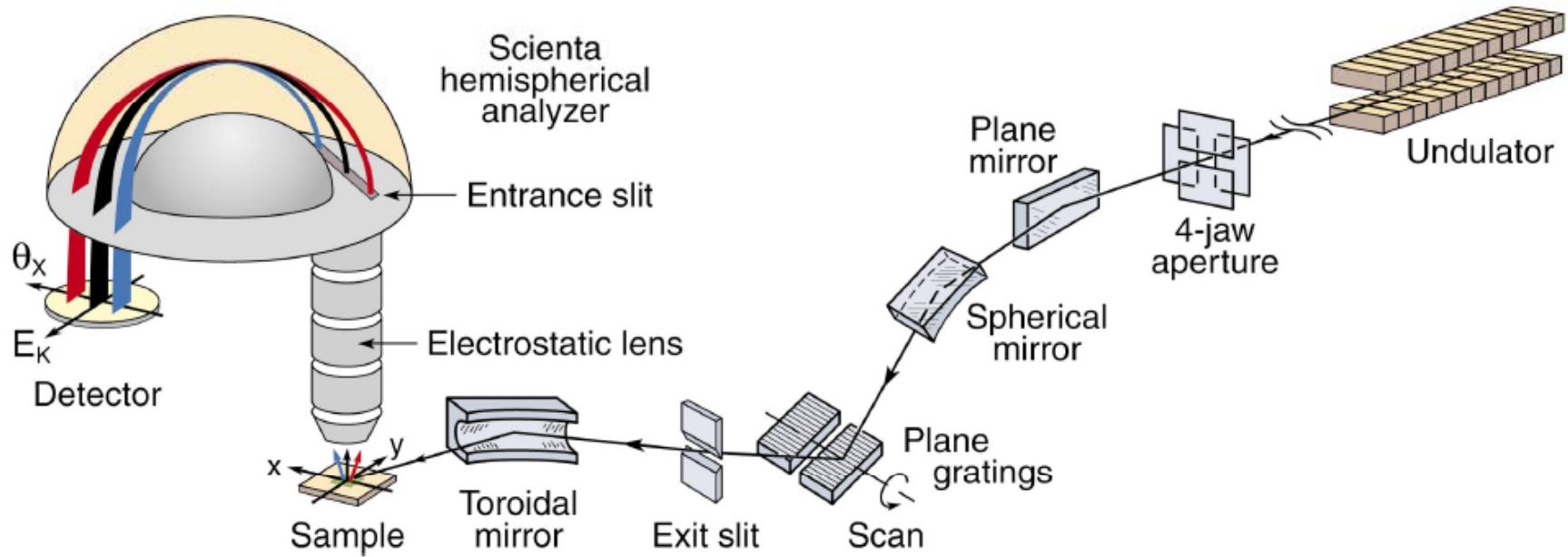
Zhi-Xun Shen

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Stanford University, Stanford, California 94305*

(Published 17 April 2003)

The last decade witnessed significant progress in angle-resolved photoemission spectroscopy (ARPES) and its applications. Today, ARPES experiments with 2-meV energy resolution and 0.2° angular resolution are a reality even for photoemission on solids. These technological advances and the improved sample quality have enabled ARPES to emerge as a leading tool in the investigation of the high- T_c superconductors. This paper reviews the most recent ARPES results on the cuprate superconductors and their insulating parent and sister compounds, with the purpose of providing an updated summary of the extensive literature. The low-energy excitations are discussed with emphasis on some of the most relevant issues, such as the Fermi surface and remnant Fermi surface, the superconducting gap, the pseudogap and d -wave-like dispersion, evidence of electronic inhomogeneity and nanoscale phase separation, the emergence of coherent quasiparticles through the superconducting transition, and many-body effects in the one-particle spectral function due to the interaction of the charge with magnetic and/or lattice degrees of freedom. Given the dynamic nature of the field, we chose to focus mainly on reviewing the experimental data, as on the experimental side a general consensus has been reached, whereas interpretations and related theoretical models can vary significantly. The first part of the paper introduces photoemission spectroscopy in the context of strongly interacting systems, along with an update on the state-of-the-art instrumentation. The second part provides an overview of the scientific issues relevant to the investigation of the low-energy electronic structure by ARPES. The rest of the paper is devoted to the experimental results from the cuprates, and the discussion is organized along conceptual lines: normal-state electronic structure, interlayer interaction, superconducting gap, coherent superconducting peak, pseudogap, electron self-energy, and collective modes. Within each topic, ARPES data from the various copper oxides are presented.

Experimental setup & condition



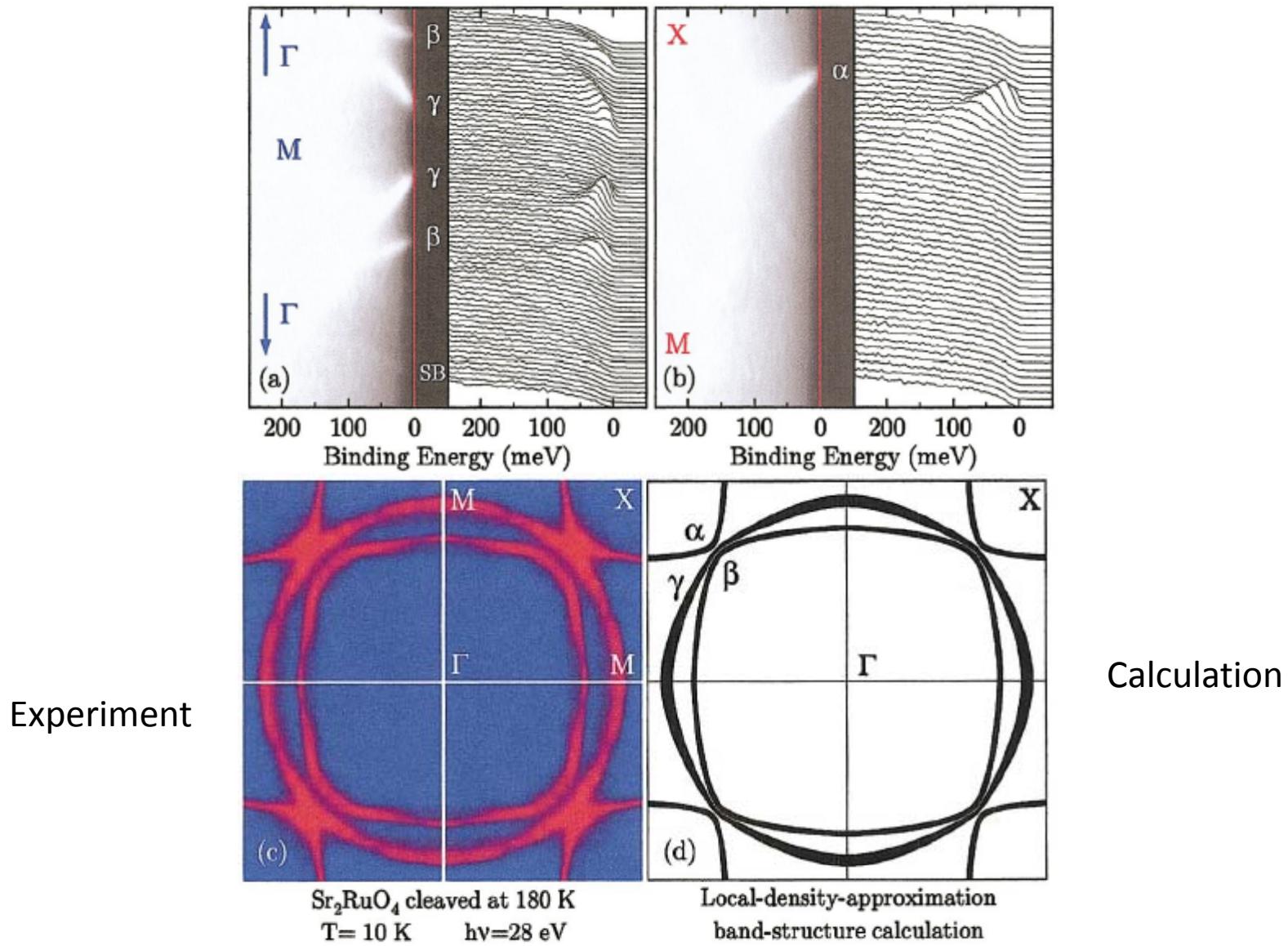
Energy Range: Ultraviolet (<100 eV)

Energy Resolution: a few meV

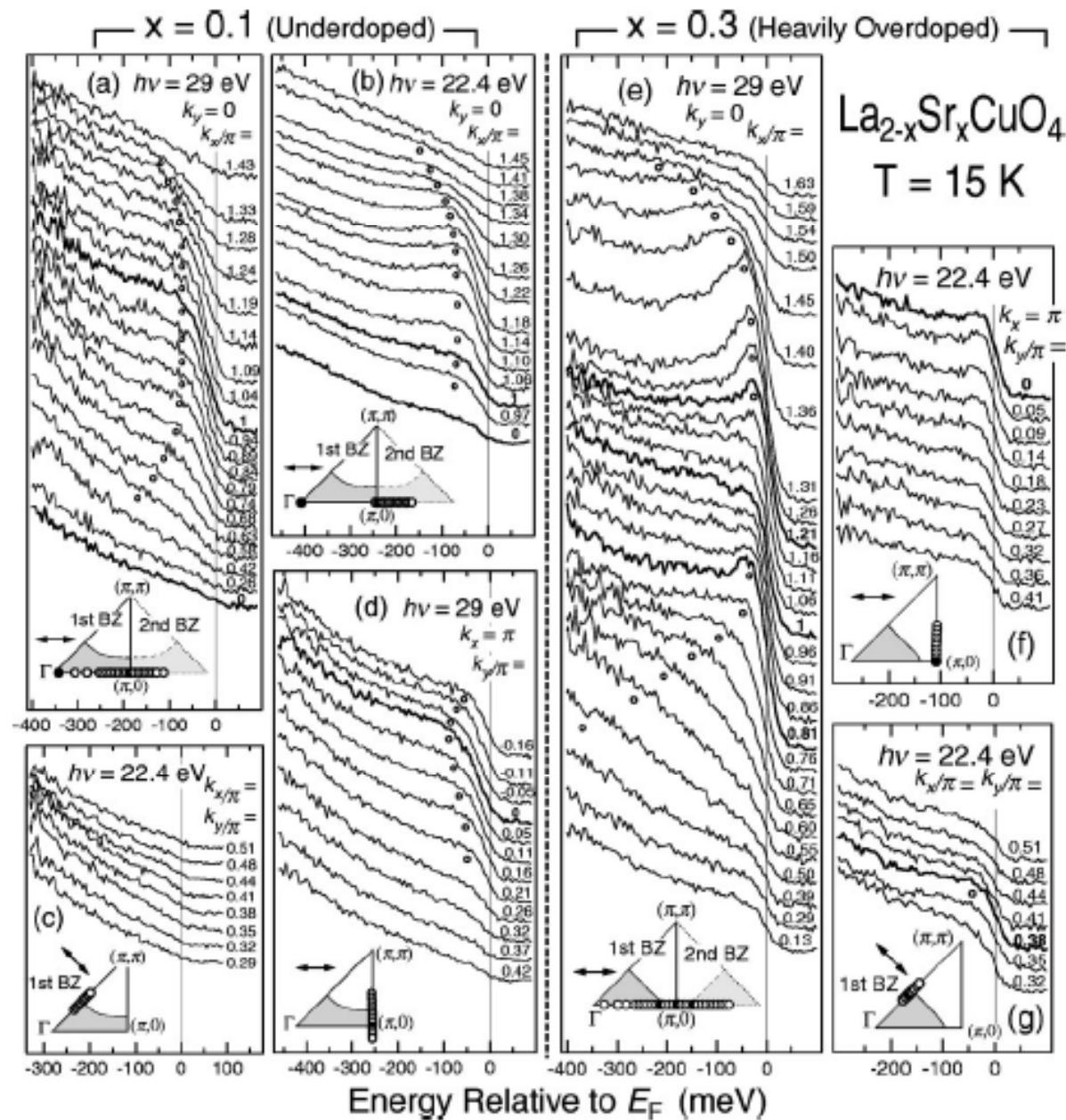
Angular Resolution: 0.2°

Pressure lower than 5×10^{-11} torr

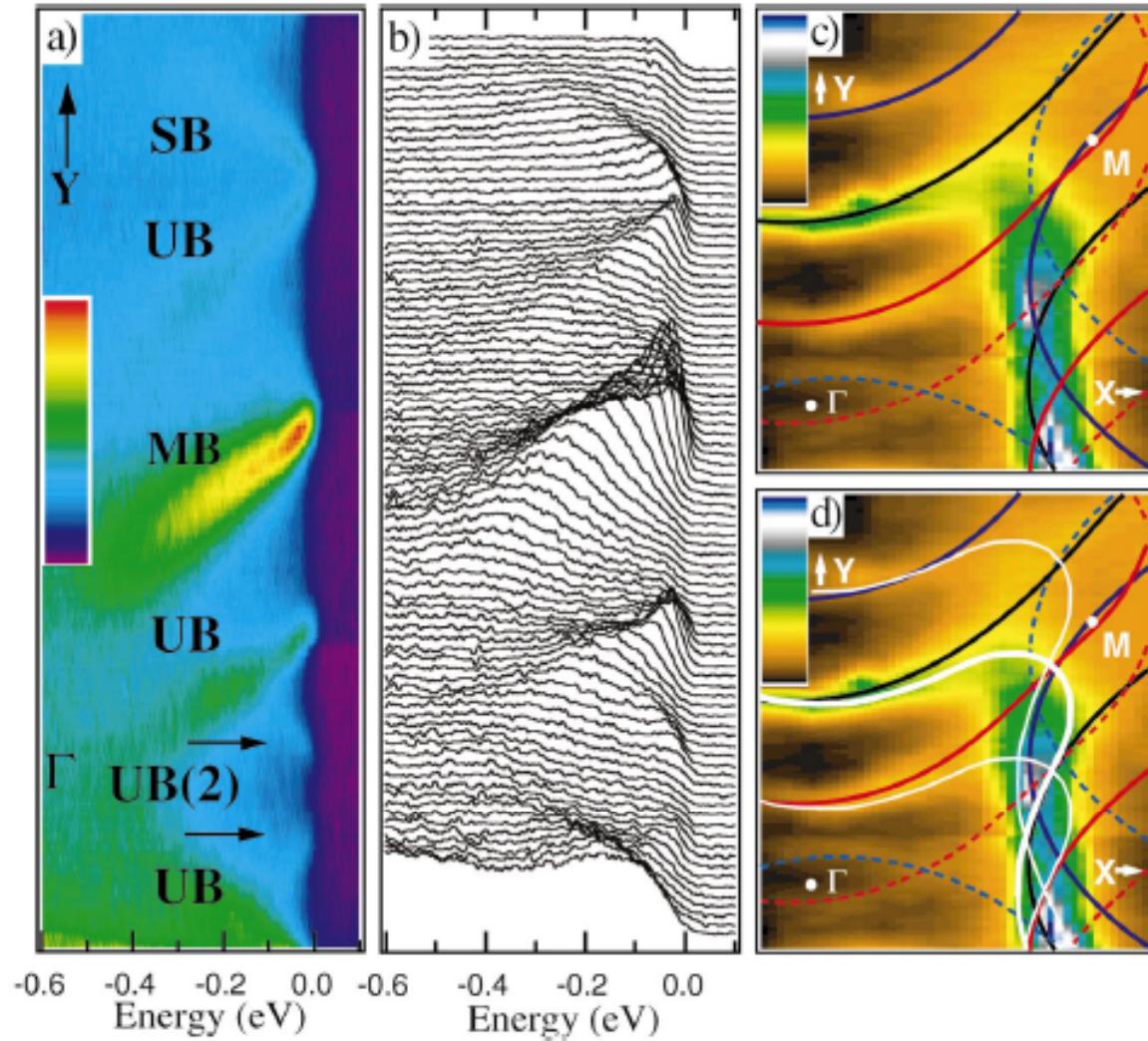
Fermi Surface



Doping and Momentum dependence



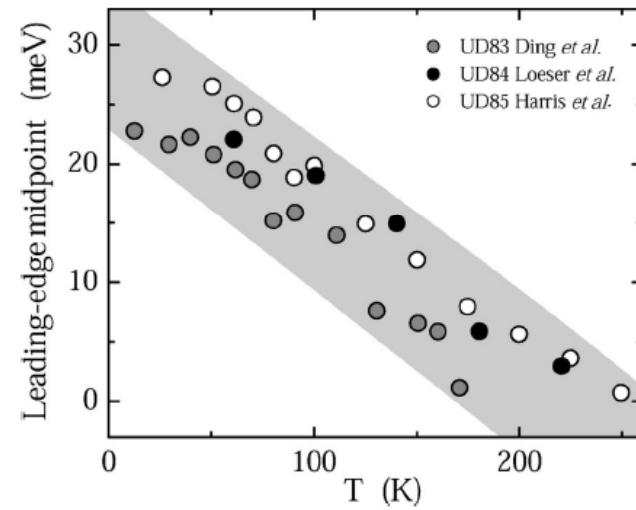
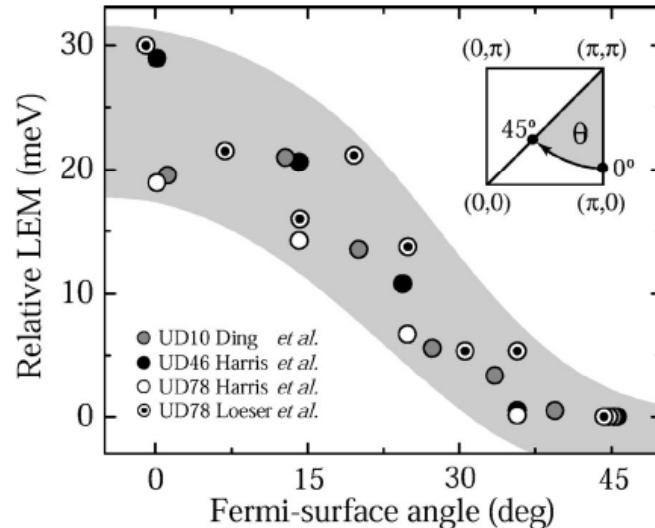
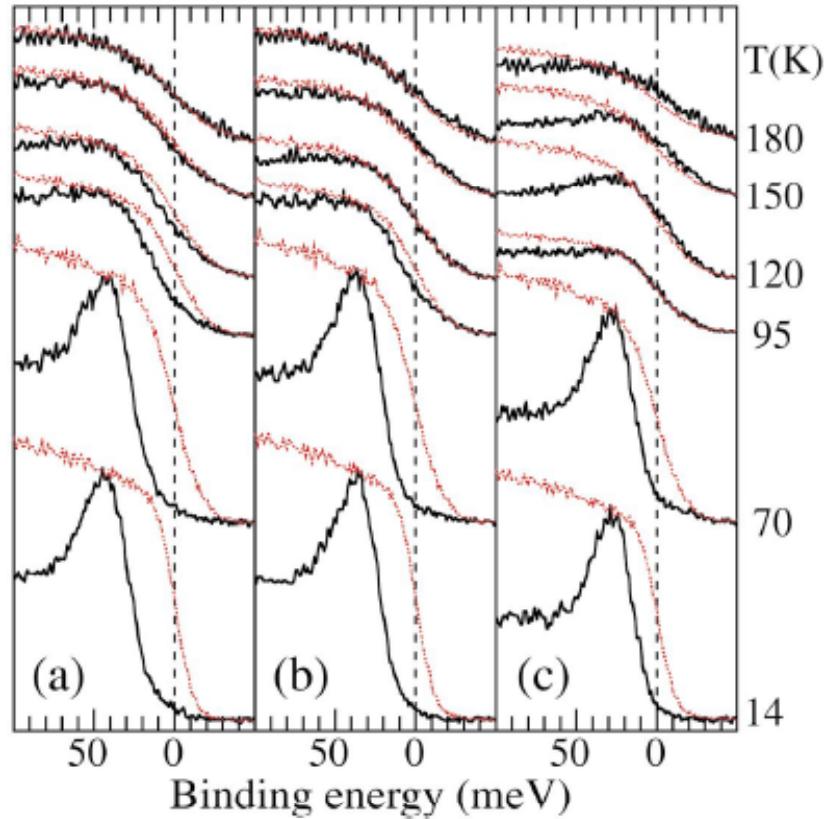
Band Structure & Fermi Surface



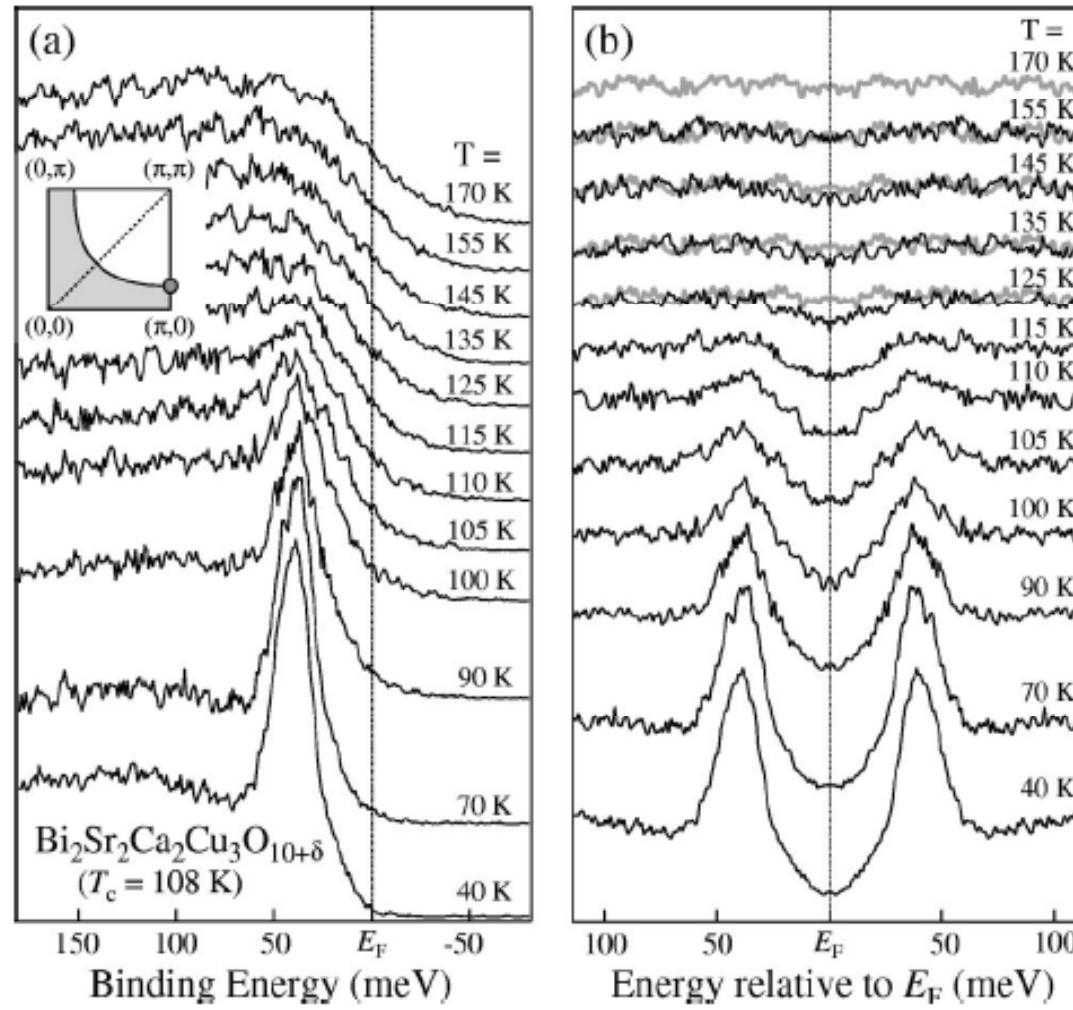
Optimally doped Bi₂2212 ($T_c=90$ K) at 40 K

Integrated intensity
map (± 100 meV)

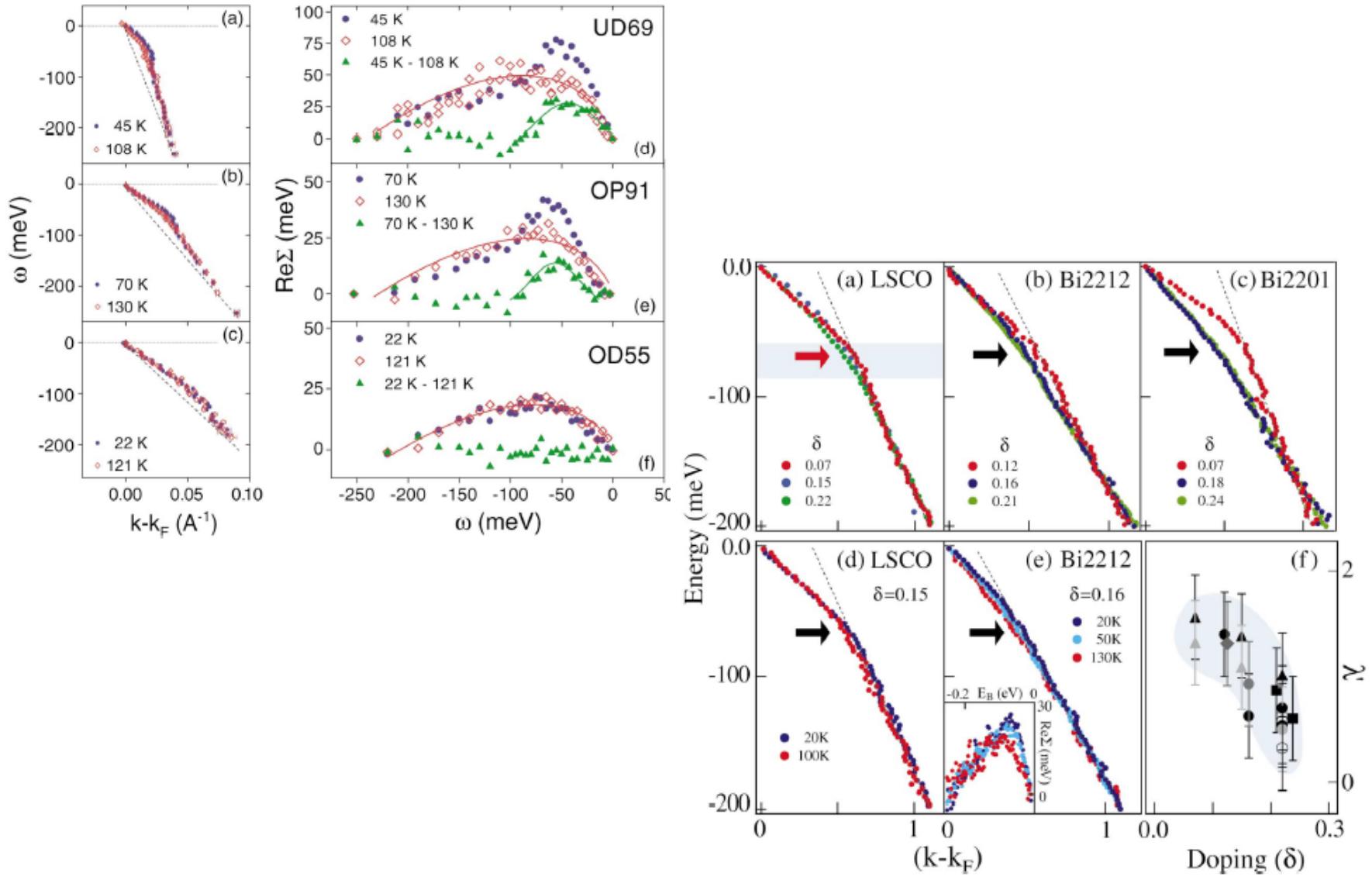
Pseudogap: T and k dependence



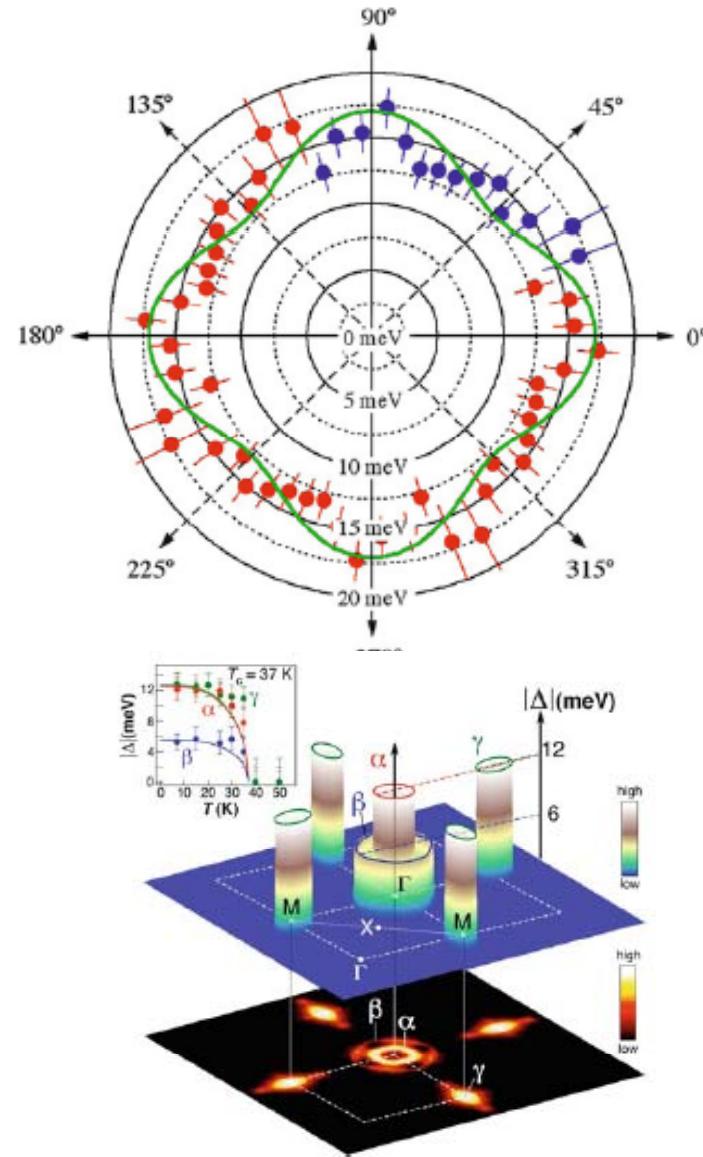
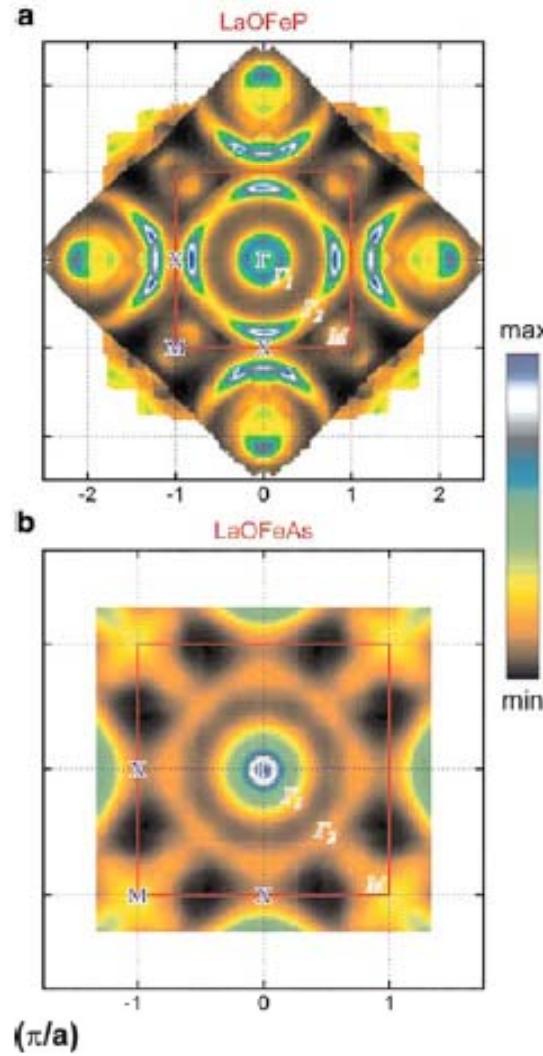
Peak-Deep-Hump structure and Superconducting Gap



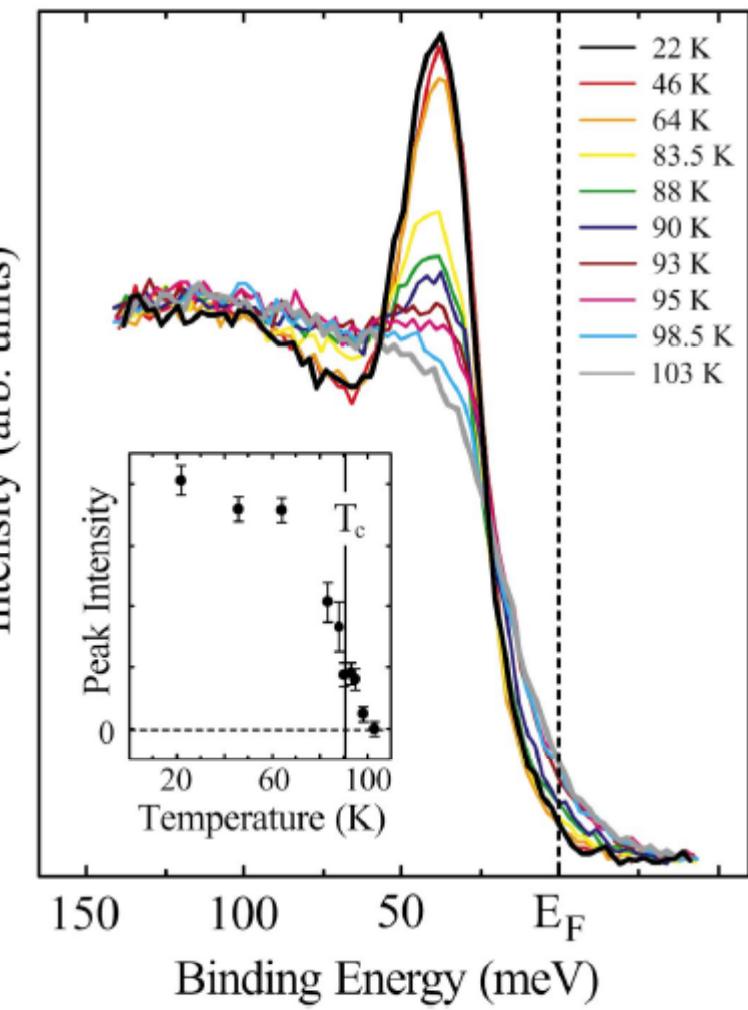
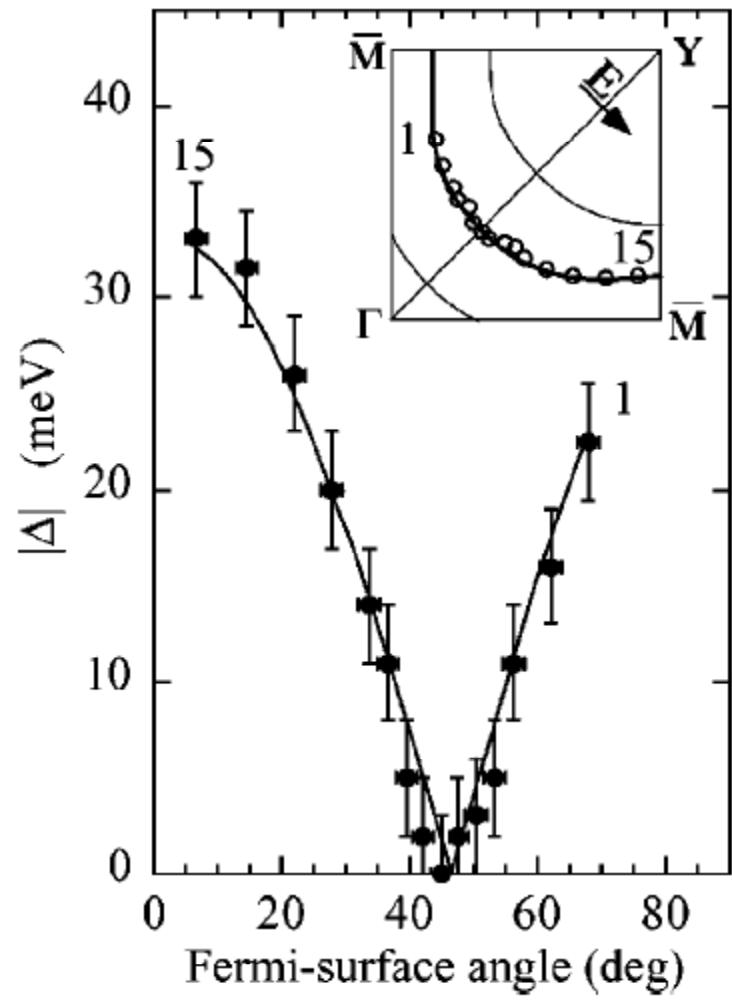
Electron-Phonon Interaction



FeAs Superconductors

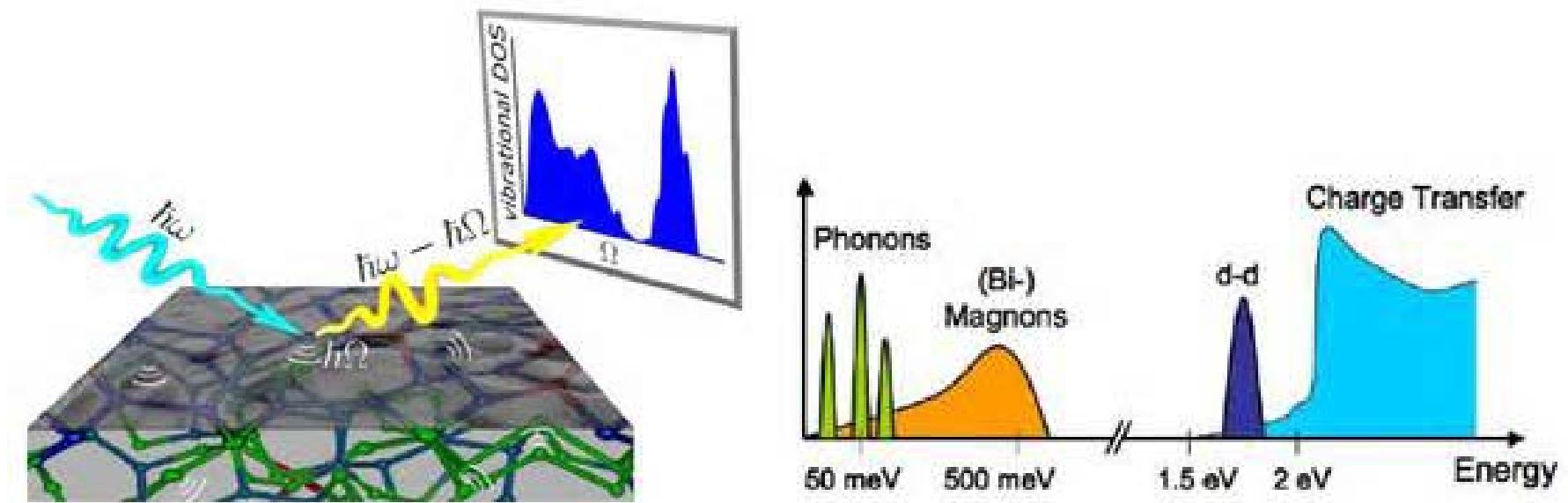


Pairing Symmetry



IXS

- Inelastic X-ray Scattering
- Electronic and dynamic excitations
Phonon structure
Electron-phonon interaction



Phonon spectroscopy by inelastic x-ray scattering

Eberhard Burkel

Physics of New Materials, Department of Physics, University of Rostock, August-Bebel-Strasse 55, 18055 Rostock, Germany

Received 24 May 1999, in final form 18 November 1999

Abstract

The present synchrotron sources with brilliant x-ray beams, due to high photon fluxes, small source sizes and high collimation, have revolutionized x-ray physics.

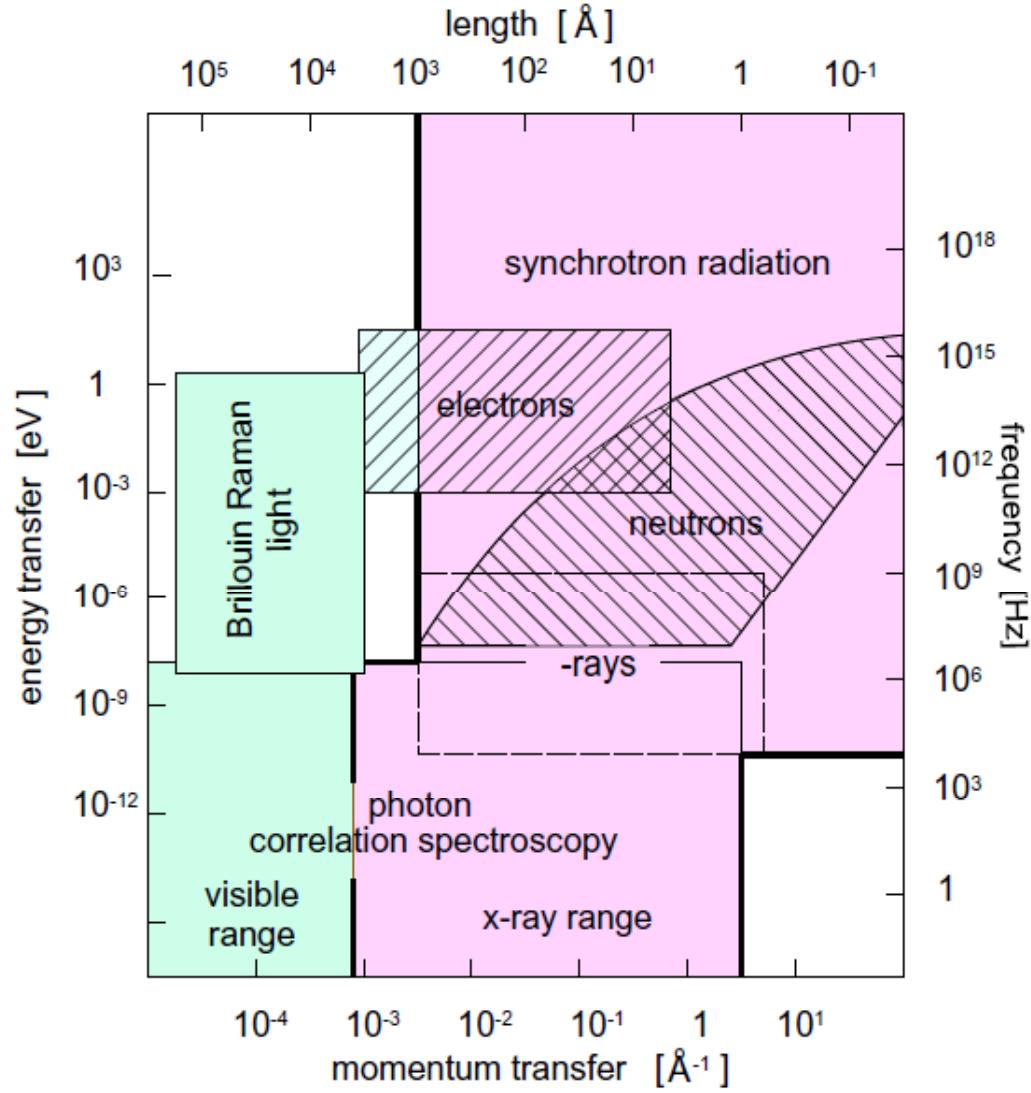
Enormous progress has been initiated in all established x-ray methods, with the aim of the development of new types of spectroscopy. This is particularly true for the spectroscopy of the dynamics in condensed matter. Meanwhile, there are two powerful x-ray methods with very high-energy resolution available for the study of low energetic excitations like phonons.

This review summarizes the developments of these methods focusing on these instrumental developments of the spectrometers using either crystal optics in close-to-backscattering geometry or nuclear resonant techniques.

Applications to measurements of phonon dispersion curves and of phonon density of states in ordered and disordered solids and in liquids are presented. It is shown how x-ray results are stimulating improvements in the theoretical approaches to the dynamics. New insights into the dynamics of liquids are discussed.

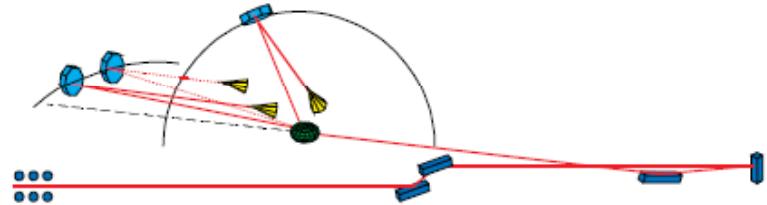
The sensitivities of the spectroscopies allow the study of vibrational behaviour in very small amounts of material even in nanometre-sized thin films or particles. We can already analyse the phonon spectrum of a monolayered nuclear resonant isotope. Prospects of the techniques are also demonstrated.

Energy-Momentum



Experimental setup

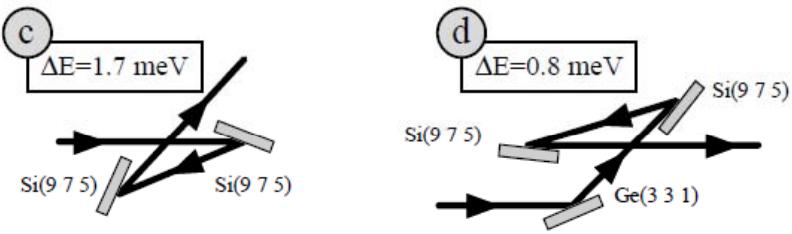
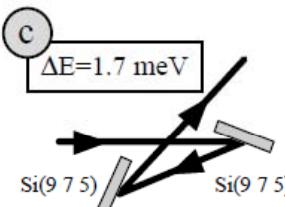
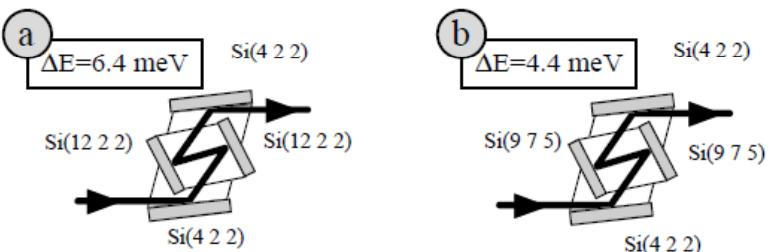
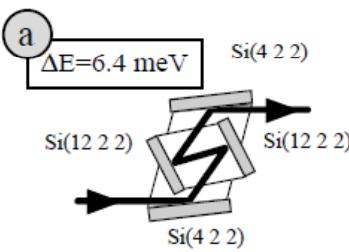
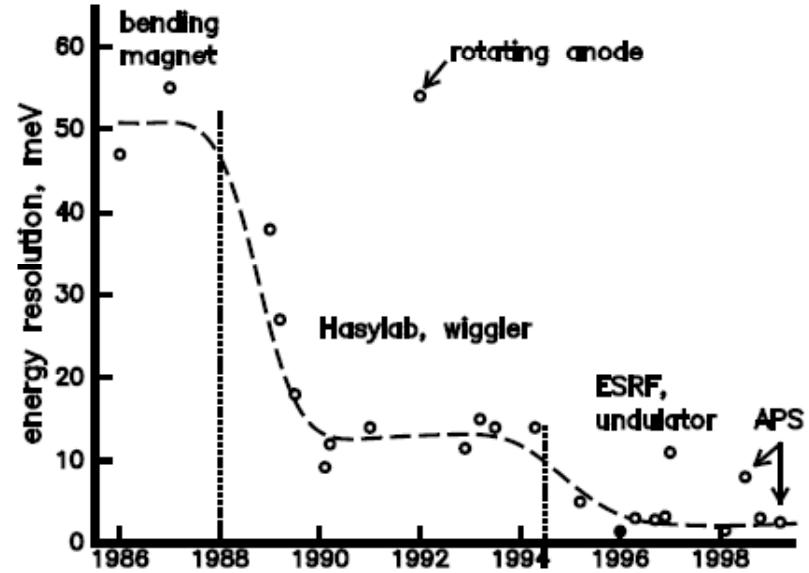
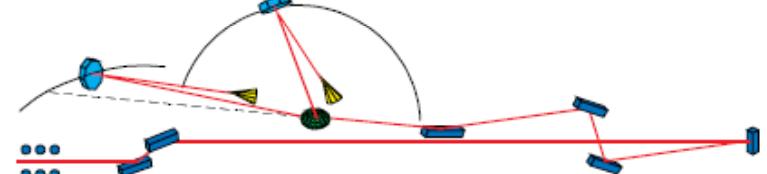
ESRF



APS



SPring8

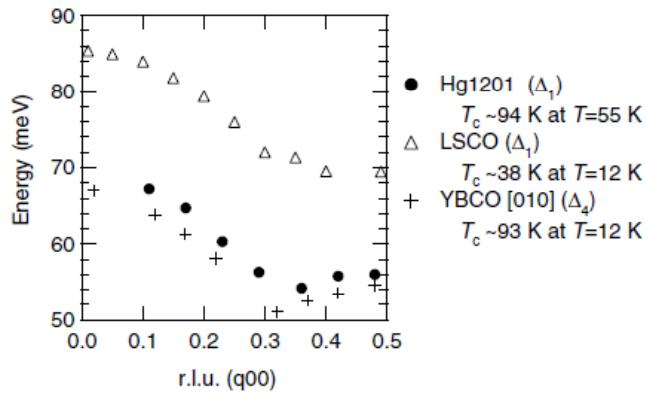
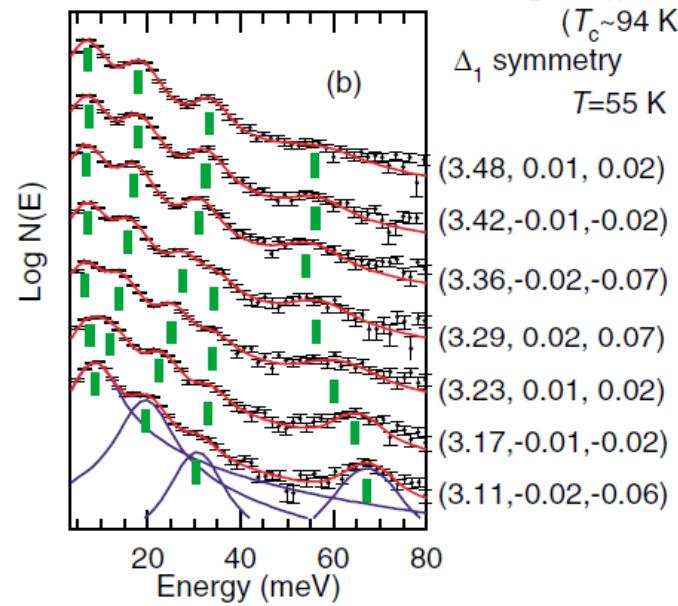
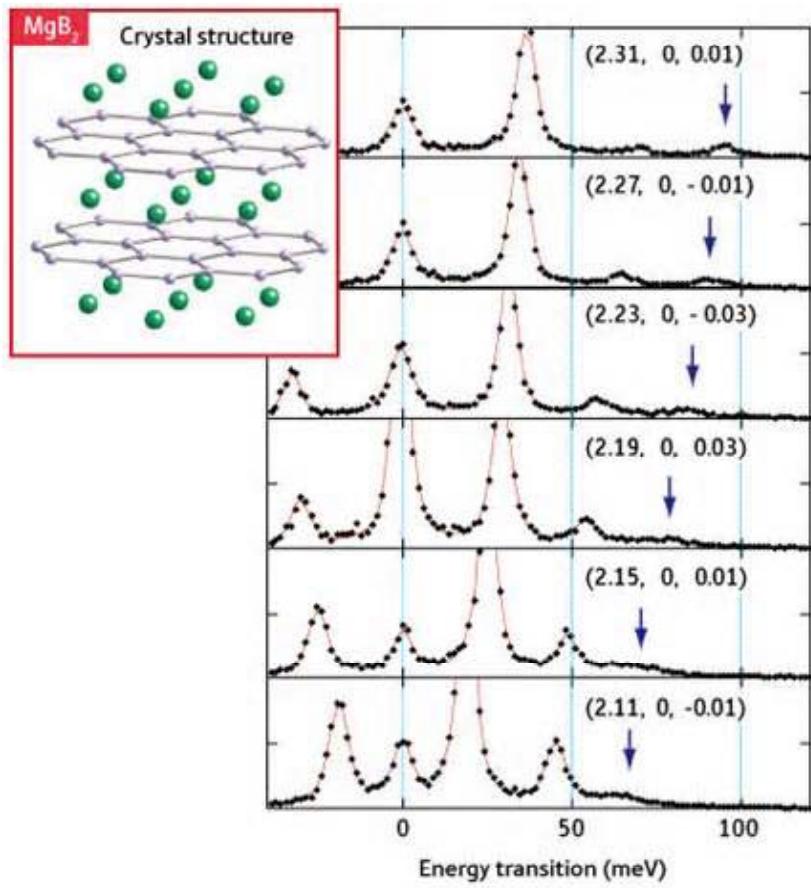


Experimental Condition

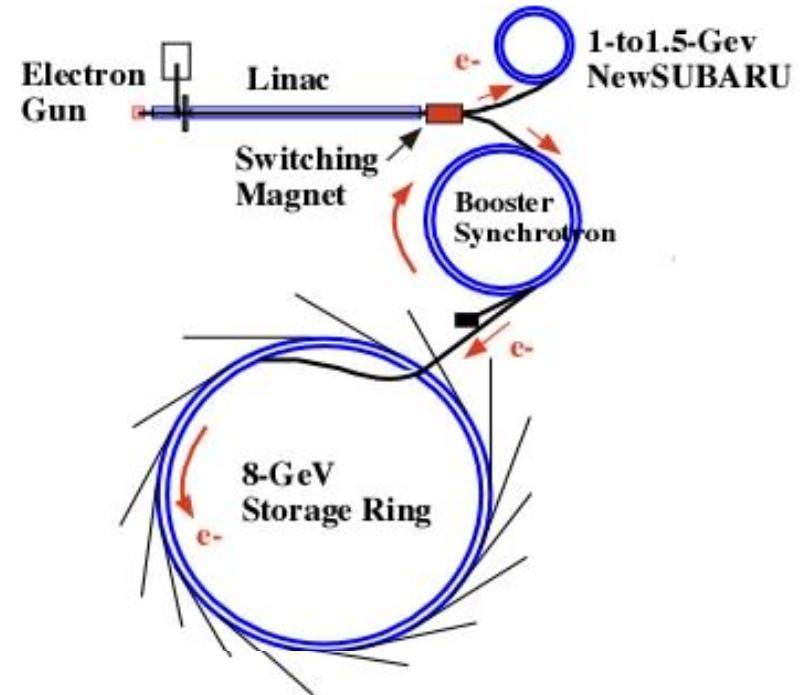
Table 2. Comparison of backscattering spectrometers at HASYLAB, at the ESRF, at APS and SPring-8.

Location	INELAX HASYLAB Hamburg, Germany	ID16 ESRF Grenoble, France	3ID APS Chicago, USA	BL35XU SPring-8 Kansai, Japan
Operational	1987	1994	1997	2000
Ring energy	4.5 GeV	Source characteristics		8.0 GeV
Ring current	140 mA	200 mA	100 mA	100 mA
Insertion device	wiggler	2 undulators	undulator	undulator
Length	2.6 m	1.6 m each	2.5 m	4.5 m
Divergence:				
vertical	0.12 mrad	24 μ rad	12 μ rad	11 μ rad
horizontal	2.6 mrad	40 μ rad	42 μ rad	35 μ rad
X-ray optics				
Pre-monochromator	Si (1 1 1) 2-crystal setting room temperature	Si (1 1 1) channel-cut at 90–120 K	diamond 2-crystal setting room temperature	Si (1 1 1) 2-crystal setting cryogenically cooled
Main monochromator	Si (h h h) backscattering spherically bent	Si (h h h) backscattering flat	Si (4 4 0) + (15 11 3) nested channel-cut	Si (h h h) backscattering flat
Focus spot	$3 \times 1 \text{ mm}^2$	$500 \times 300 \mu\text{m}^2$	$600 \times 500 \mu\text{m}^2$	$100 \times 150 \mu\text{m}^2$
Analyser	Si (h h h) spherically bent	Si (h h h) spherically bent	Si (h h h) spherically bent	Si (h h h) spherically bent

Examples



SPring8 Synchrotron



BL35- Inelastic X-ray Scattering

- BL22XU JAEA Quantum Structural Science (Japan Atomic Energy Agency)
- BL23SU JAEA Actinide Science (Japan Atomic Energy Agency)
- BL24XU Hyogo ID (Hyogo Prefecture)
- ★ BL25SU Soft X-ray Spectroscopy of Solid
- ◆ BL26B1 RIKEN Structural Genomics I
- ◆ BL26B2 RIKEN Structural Genomics II
- ★ BL27SU Soft X-ray Photochemistry
- BL28XU Advanced Basic Science for Battery Innovation (ABSBI) (Kyoto University)
- ★ BL28B2 White Beam X-ray Diffraction
- ◆ BL29XU RIKEN Coherent X-ray Optics
- ◆ BL32XU RIKEN Targeted Proteins
- BL32B2 Pharmaceutical Industry (Pharmaceutical Consortium for Protein Structure Analysis)
- BL33XU TOYOTA (TOYOTA Central R&D Labs., Inc.)
- BL33LEP Laser-Electron Photon (Research Center for Nuclear Physics, Osaka University)
- ★ BL35XU High Resolution Inelastic Scattering
- ★ BL37XU Trace Element Analysis
- ★ BL38B1 Structural Biology III
- BL38B2 Accelerator Beam Diagnosis
- ★ BL39XU Magnetic Materials
- ★ BL40XU High Flux
- ★ BL40B2 Structural Biology II
- ★ BL41XU Structural Biology I
- ★ BL43IR Infrared Materials Science
- ◆ BL43LXU RIKEN Quantum Nano Dynamics
- BL44XU Macromolecular Assemblies (Institute for Protein Research, Osaka University)
- ◆ BL44B2 RIKEN Materials Science
- ◆ BL45XU RIKEN Structural Biology I
- ★ BL46XU Engineering Science Research III
- ★ BL47XU HXPES-MCT

SPring-8
Beamline Map

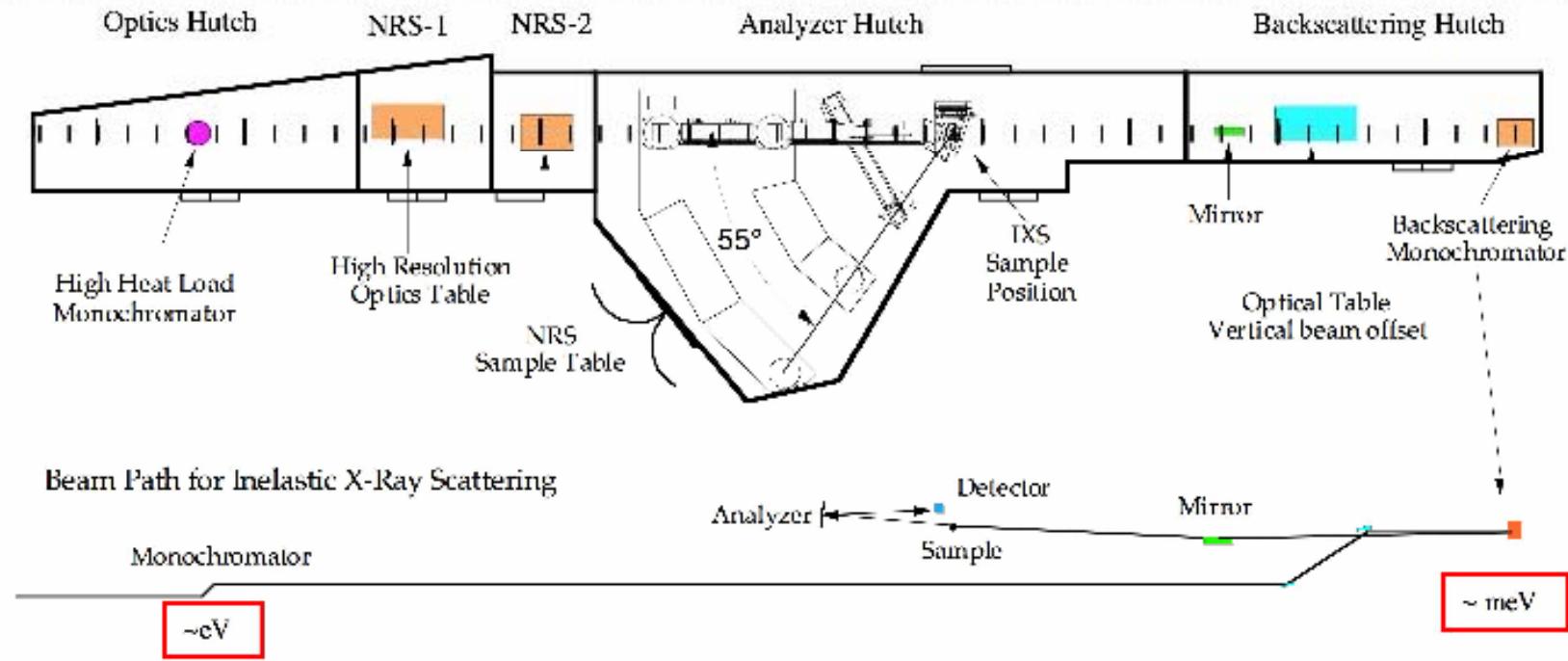
Total number of beamlines : 62

- Insertion Device (6 m) : 34 (—)
- Insertion Device (30 m) : 4 (—)
- Bending Magnet : 24 (—)

Main Bldg.

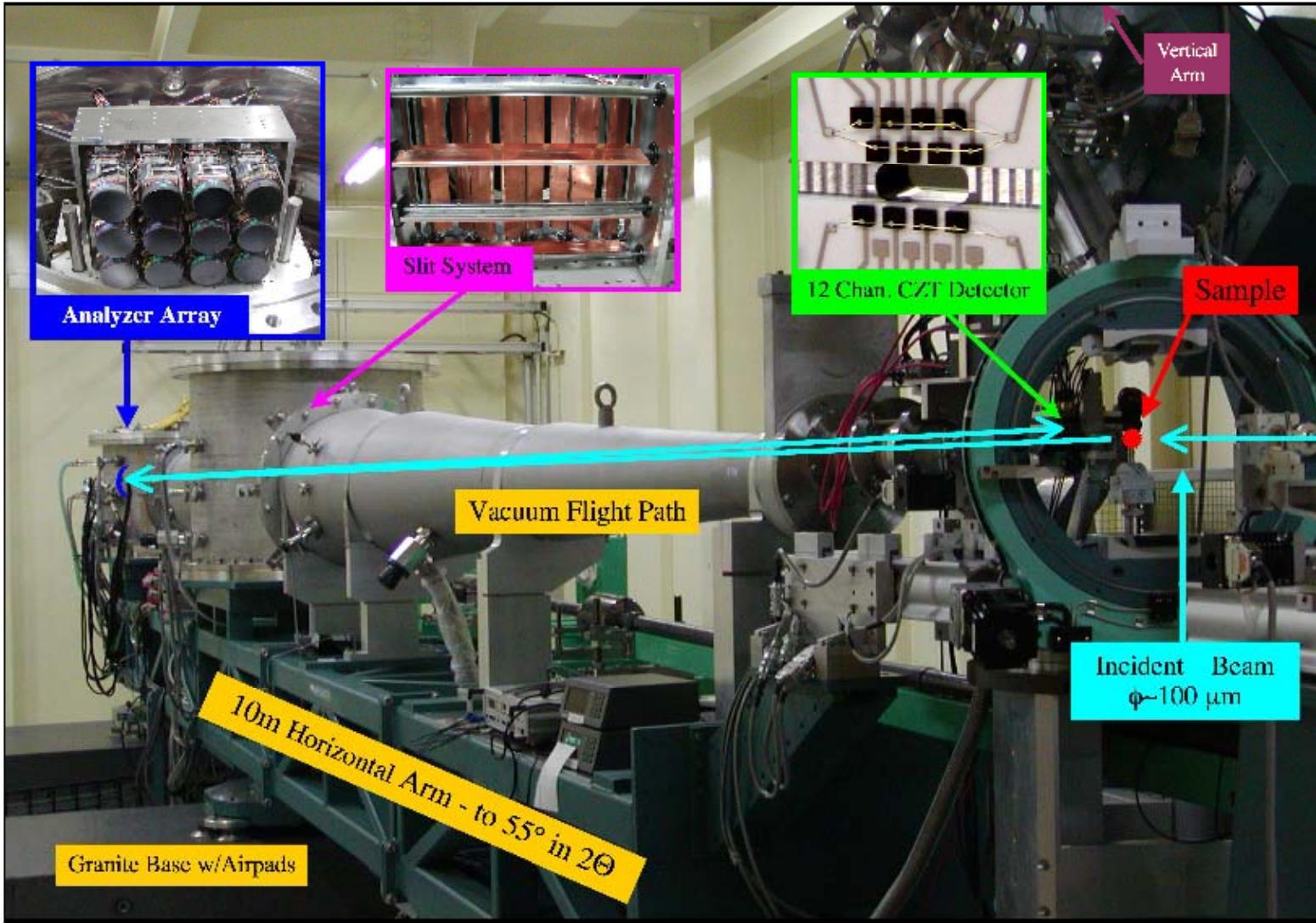
- Medical and Imaging I BL20B2 ★
- Medical and Imaging II BL20XU ★
- Engineering Science Research I BL19B2 ★
- RIKEN SR Physics BL19LXU ◆
- RIKEN Coherent Soft X-ray Spectroscopy BL17SU ◆
- Sunbeam BM BL16B2 ●
(Industrial Consortium)
- Sunbeam ID BL16XU ●
(Industrial Consortium)
- WEBRAM BL15XU ●
(National Institute for Materials Science)
- Engineering Science Research II BL14B2 ★
- JAEA Materials Science BL14B1 ●
(Japan Atomic Energy Agency)
- Surface and Interface Structures BL13XU ★
- NSRRRC BM BL12B2 ●
(National Synchrotron Radiation Research Center)
- NSRRRC ID BL12XU ●
(National Synchrotron Radiation Research Center)
- JAEA Quantum Dynamics BL11XU ●
(Japan Atomic Energy Agency)
- High Pressure Research BL10XU ★
- Nuclear Resonant Scattering BL09XU ★
- Hyogo BM (Hyogo Prefecture) BL08B2 ●
- High Energy Inelastic Scattering BL08W ★
- Univ-of-Tokyo BL07LSU ●
(The University of Tokyo)
- Accelerator Beam Diagnosis BL05SS ■
- High Energy X-ray Diffraction BL04B2 ★
- High Temperature and High Pressure Research BL04B1 ★
- Advanced Softmaterial BL03XU ●
(Advanced Softmaterial Beamline Consortium)
- Powder Diffraction BL02B2 ★
- Single Crystal Structure Analysis BL02B1 ★
- XAFS BL01B1 ★

BL35XU Layout

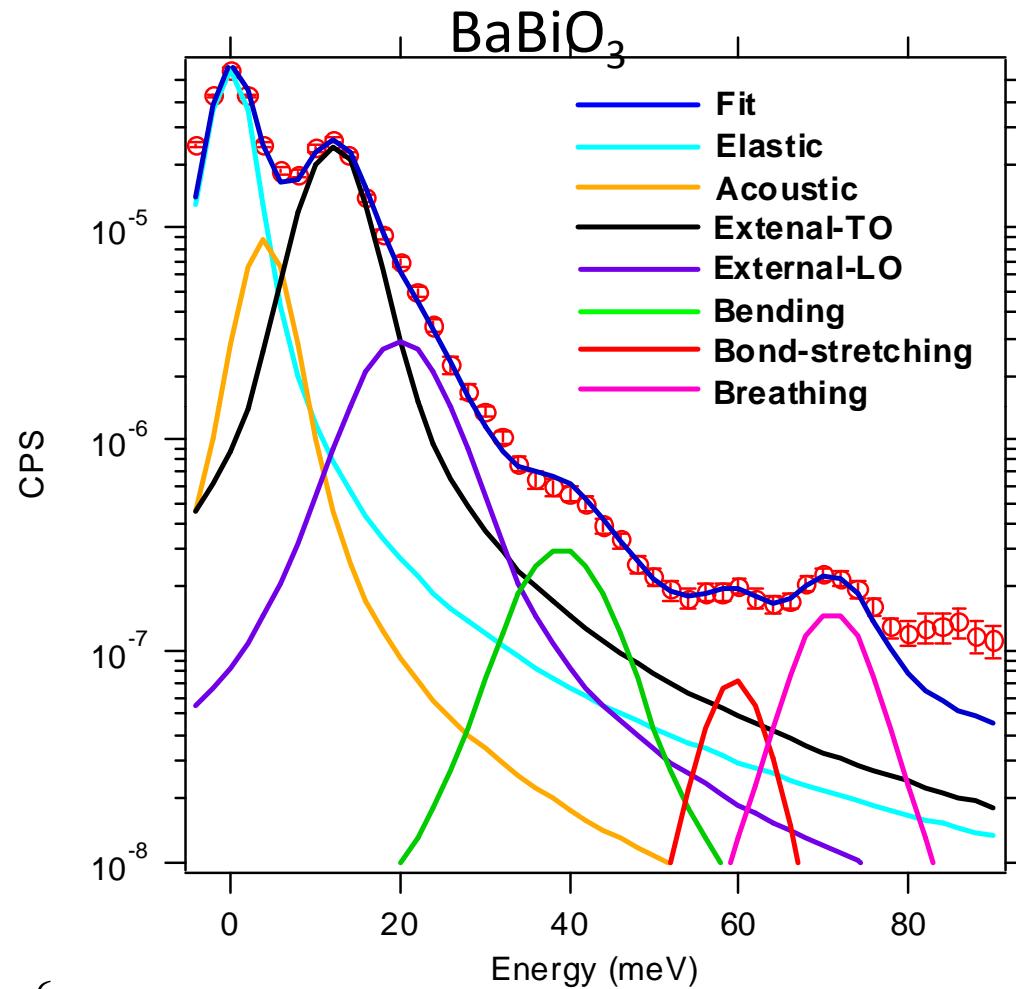


Energy (keV)	Si Order	Resolution (meV)	Flux at Sample (GHz)
15.816	(8 8 8)	6	30
17.794	(9 9 9)	3	10
21.747	(11 11 11)	1.5	3.5
25.702	(13 13 13)	1.0	0.8

Experimental Station

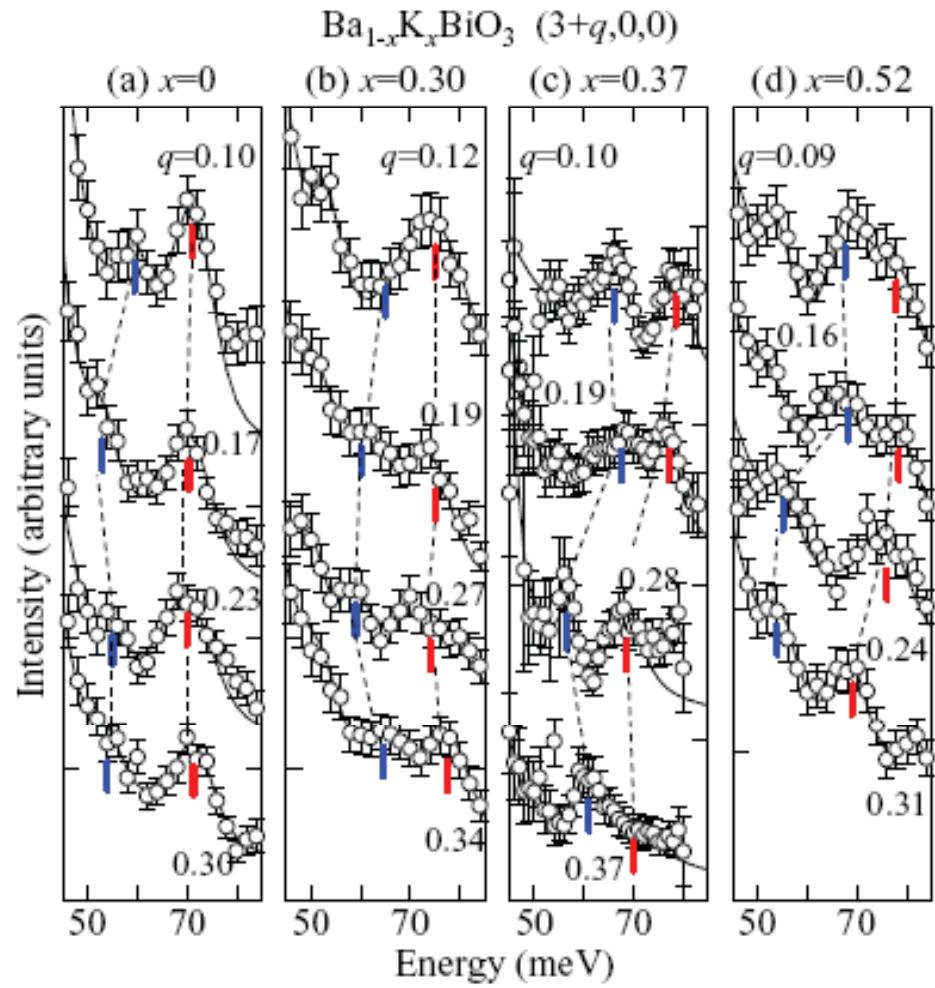
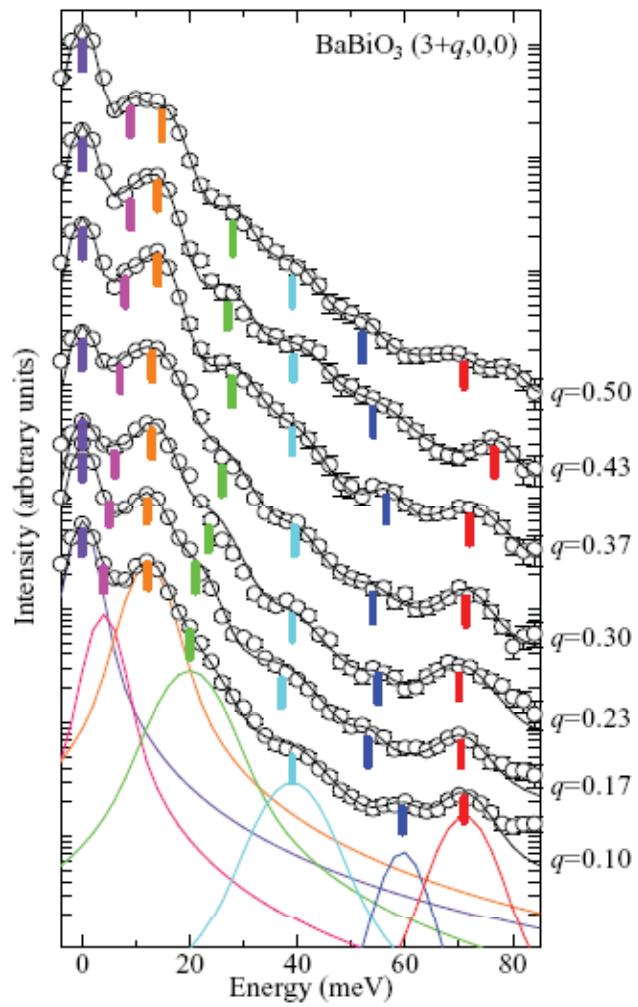


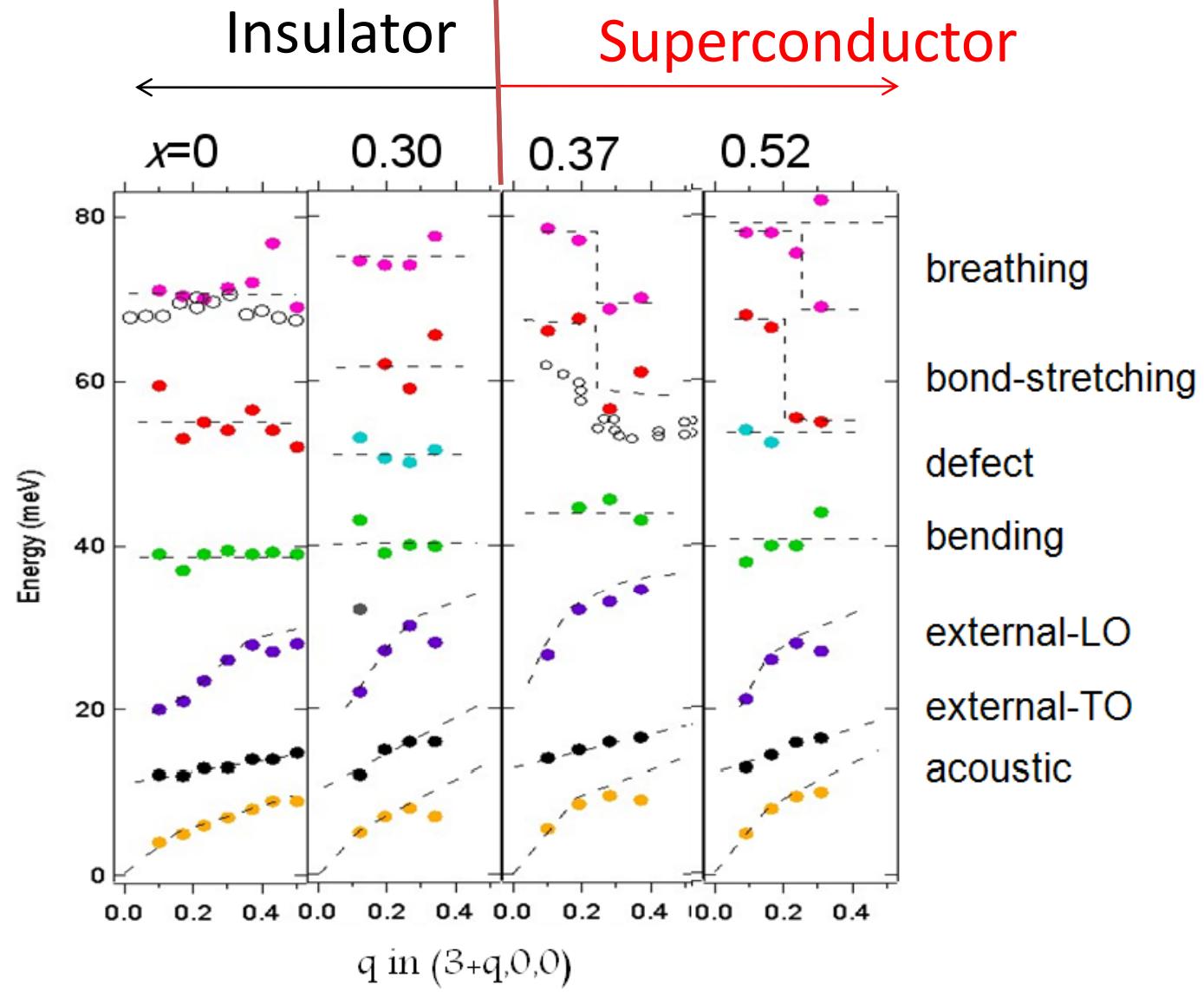
Phonon Spectrum



$$I(\omega) = I_0 \left\{ \frac{2\eta}{\pi} \frac{\Gamma}{\Gamma^2 + 4(\omega - \omega_0)^2} + \frac{2(1-\eta)}{\Gamma} \left(\frac{\ln 2}{\pi} \right)^{0.5} \exp(-4 \ln 2 \left(\frac{\omega - \omega_0}{\Gamma} \right)^2) \right\}$$

Momentum & Doping dependence





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Softening of bond-stretching phonon mode in $\text{Ba}_{1-x}\text{K}_x\text{BiO}_3$ at the metal-insulator transition

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The dispersion of phonons in $\text{Ba}_{1-x}\text{K}_x\text{BiO}_3$ along the $(3 + q, 0, 0)$ direction in reciprocal space was determined for $x = 0, 0.30, 0.37$, and 0.52 using high-resolution inelastic x-ray scattering. The observed phonon energies

Thank You